Freescale Semiconductor Technical Data

Document Number: MPC8313EEC

Rev. 0, 06/2007

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications

This document provides an overview of the MPC8313E PowerQUICCTM II Pro processor features, including a block diagram showing the major functional components. The MPC8313E is a cost-effective, low-power, highly integrated host processor that addresses the requirements of several printing and imaging, consumer, and industrial applications, including main CPUs and I/O processors in printing systems, networking switches and line cards, wireless LANs (WLANs), network access servers (NAS), VPN routers, intelligent NIC, and industrial controllers. The MPC8313E extends the PowerQUICCTM family, adding higher CPU performance, additional functionality, and faster interfaces while addressing the requirements related to time-to-market, price, power consumption, and package size.

1 Overview

The MPC8313E incorporates the e300c3 core, which includes 16 Kbytes of L1 instruction and data caches and on-chip memory management units (MMUs). The MPC8313E has interfaces to dual enhanced three-speed 10, 100, 1000 Mbps Ethernet controllers, a DDR1/DDR2 SDRAM memory controller, an enhanced local bus controller, a 32-bit PCI controller, a dedicated security

Contents

| 1. | Overview | 1 |
|-----|--|----|
| 2. | Electrical Characteristics | 7 |
| 3. | Power Characteristics | 1 |
| 4. | Clock Input Timing | 3 |
| 5. | RESET Initialization | 4 |
| 6. | DDR and DDR2 SDRAM | 6 |
| 7. | DUART 2 | 21 |
| 8. | Ethernet: Three-Speed Ethernet, MII Management . 2 | 23 |
| 9. | USB 3 | 5 |
| 10. | Local Bus 3 | 37 |
| 11. | JTAG 4 | 2 |
| 12. | I^2C 4 | 5 |
| 13. | PCI 4 | 8 |
| 14. | Timers | 1 |
| 15. | GPIO 5 | 2 |
| 16. | IPIC 5 | 3 |
| 17. | SPI | ,4 |
| 18. | Package and Pin Listings 5 | 6 |
| 19. | Clocking 6 | 59 |
| 20. | Thermal | 16 |
| 21. | System Design Information 8 | 31 |
| 22. | Document Revision History | 37 |
| 23 | Ordering Information 8 | ۲7 |

This document contains information on a new product. Specifications and information herein are subject to change without notice.



Overview

engine, a USB 2.0 dual-role controller and an on-chip full-speed PHY, a programmable interrupt controller, dual I²C controllers, a 4-channel DMA controller, and a general-purpose I/O port. A block diagram of the MPC8313E is shown in Figure 1.

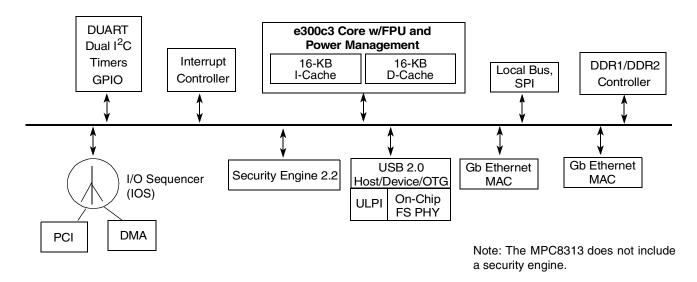


Figure 1. MPC8313E Block Diagram

The MPC8313E's security engine (SEC 2.2) allows CPU-intensive cryptographic operations to be offloaded from the main CPU core. The security-processing accelerator provides hardware acceleration for the DES, 3DES, AES, SHA-1, and MD-5 algorithms.

1.1 MPC8313E Features

The following features are supported in the MPC8313E.

- Embedded PowerPCTM e300 processor core; operates at up to 333 MHz.
- High-performance, low-power, and cost-effective host processor
- DDR1/DDR2 memory controller—one 16-/32-bit interface at up to 333 MHz supporting both DDR1 and DDR2
- e300c3 core, built on Power ArchitectureTM technology, with 16-Kbyte instruction cache and 16-Kbyte data cache, a floating point unit, and two integer units
- Peripheral interfaces such as 32-bit PCI interface with up to 66-MHz operation, 16-bit enhanced local bus interface with up to 66-MHz operation, and USB 2.0 (full speed) with an on-chip PHY.
- Security engine provides acceleration for control and data plane security protocols
- Power management controller for low-power consumption
- High degree of software compatibility with previous-generation PowerQUICC processor-based designs for backward compatibility and easier software migration

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

3

1.2 Serial Interfaces

The following interfaces are supported in the MPC8313E.

• Dual UART, dual I²C, and an SPI interface

1.3 Security Engine

The security engine is optimized to handle all the algorithms associated with IPSec, IEEE Std. 802.11iTM, and iSCSI. The security engine contains one crypto-channel, a controller, and a set of crypto execution units (EUs). The execution units are:

- Data encryption standard execution unit (DEU), supporting DES and 3DES
- Advanced encryption standard unit (AESU), supporting AES
- Message digest execution unit (MDEU), supporting MD5, SHA1, SHA-224, SHA-256, and HMAC with any algorithm
- One crypto-channel supporting multi-command descriptor chains

1.4 DDR Memory Controller

The MPC8313E DDR1/DDR2 memory controller includes the following features:

- Single 16- or 32-bit interface supporting both DDR1 and DDR2 SDRAM
- Support for up to 333-MHz
- Support for two physical banks (chip selects), each bank independently addressable
- 64-Mbit to 1-Gbit devices with x8/x16/x32 data ports (no direct x4 support)
- Support for one 16-bit device or two 8-bit devices on a 16-bit bus OR one 32-bit device or two 16-bit devices on a 32-bit bus
- Support for up to 16 simultaneous open pages
- Supports auto refresh
- On-the-fly power management using CKE
- 1.8-/2.5-V SSTL2 compatible I/O

1.5 PCI Controller

The MPC8313E PCI controller includes the following features:

- PCI specification revision 2.3 compatible
- Single 32-bit data PCI interface operates at up to 66 MHz
- PCI 3.3-V compatible (not 5-V compatible)
- Support for host and agent modes
- On-chip arbitration, supporting three external masters on PCI
- Selectable hardware-enforced coherency

1.6 USB Dual-Role Controller

The MPC8313E USB controller includes the following features:

- Supports USB on-the-go mode, which includes both device and host functionality, when using an external ULPI (UTMI + low-pin interface) PHY
- Complies with USB Specification, Rev. 2.0
- Supports operation as a stand-alone USB device
 - Supports one upstream facing port
 - Supports three programmable USB endpoints
- Supports operation as a stand-alone USB host controller
 - Supports USB root hub with one downstream-facing port
 - Enhanced host controller interface (EHCI) compatible
- Supports full-speed (12 Mbps), and low-speed (1.5 Mbps) operation. Low-speed operation is supported only in host mode.
- Supports UTMI + low pin interface (ULPI) or on-chip USB-2.0 full-speed PHY

1.7 Dual Enhanced Three-Speed Ethernet Controllers (eTSECs)

The MPC8313E eTSECs include the following features:

- Two RGMII/SGMII/MII/RMII/RTBI interfaces
- Two controllers designed to comply with IEEE Stds. 802.3TM, 802.3uTM, 802.3xTM, 802.3zTM, 802.3abTM
- Support for Wake-on-Magic Packet[™], a method to bring the device from standby to full operating mode
- MII management interface for external PHY control and status
- Three-speed support (10/100/1000 Mbps)
- On-chip high-speed serial interface to external SGMII PHY interface
- Support for IEEE Std. 1588TM
- Support for two full-duplex FIFO interface modes
- Multiple PHY interface configuration
- TCP/IP acceleration and QoS features available
- IP v4 and IP v6 header recognition on receive
- IP v4 header checksum verification and generation
- TCP and UDP checksum verification and generation
- Per-packet configurable acceleration
- Recognition of VLAN, stacked (queue in queue) VLAN, IEEE Std. 802.2TM, PPPoE session, MPLS stacks, and ESP/AH IP-security headers
- Transmission from up to eight physical queues.
- Reception to up to eight physical queues

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

5

- Full- and half-duplex Ethernet support (1000 Mbps supports only full-duplex):
- IEEE Std. 802.3 full-duplex flow control (automatic PAUSE frame generation or software-programmed PAUSE frame generation and recognition)
- Programmable maximum frame length supports jumbo frames (up to 9.6 Kbytes) and IEEE Std. 802.1TM virtual local area network (VLAN) tags and priority
- VLAN insertion and deletion
- Per-frame VLAN control word or default VLAN for each eTSEC
- Extracted VLAN control word passed to software separately
- Retransmission following a collision
- CRC generation and verification of inbound/outbound packets
- Programmable Ethernet preamble insertion and extraction of up to 7 bytes
- MAC address recognition:
- Exact match on primary and virtual 48-bit unicast addresses
- VRRP and HSRP support for seamless router fail-over
- Up to 16 exact-match MAC addresses supported
- Broadcast address (accept/reject)
- Hash table match on up to 512 multicast addresses
- Promiscuous mode
- Buffer descriptors backward compatible with MPC8260 and MPC860T 10/100 Ethernet programming models
- RMON statistics support
- 10-Kbyte internal transmit and 2-Kbyte receive FIFOs
- MII management interface for control and status

1.8 Programmable Interrupt Controller (PIC)

The programmable interrupt controller (PIC) implements the necessary functions to provide a flexible solution for general-purpose interrupt control. The PIC programming model supports 5 external and 34 internal discrete interrupt sources. Interrupts can also be redirected to an external interrupt controller.

1.9 Power Management Controller (PMC)

The MPC8313E power management controller includes the following features:

- Provides power management when the device is used in both host and agent modes
- Supports PCI Power Management 1.2 D0, D1, D2, D3hot, and D3cold states
- On-chip split power supply controlled through external power switch for minimum standby power
- Support for PME generation in PCI agent mode, PME detection in PCI host mode
- Supports wake-up from Ethernet (magic packet), USB, GPIO, and PCI (PME input as host)

1.10 Serial Peripheral Interface (SPI)

The serial peripheral interface (SPI) allows the MPC8313E to exchange data between other PowerQUICC family chips, Ethernet PHYs for configuration, and peripheral devices such as EEPROMs, real-time clocks, A/D converters, and ISDN devices.

The SPI is a full-duplex, synchronous, character-oriented channel that supports a four-wire interface (receive, transmit, clock, and slave select). The SPI block consists of transmitter and receiver sections, an independent baud-rate generator, and a control unit.

1.11 DMA Controller, Dual I²C, DUART, Local Bus Controller, and Timers

The MPC8313E provides an integrated four-channel DMA controller with the following features:

- Allows chaining (both extended and direct) through local memory-mapped chain descriptors (accessible by local masters).
- Supports misaligned transfers

There are two I^2C controllers. These synchronous, multi-master buses can be connected to additional devices for expansion and system development.

The DUART supports full-duplex operation and is compatible with the PC16450 and PC16550 programming models. 16-byte FIFOs are supported for both the transmitter and the receiver.

The MPC8313E local bus controller (LBC) port allows connections with a wide variety of external DSPs and ASICs. Three separate state machines share the same external pins and can be programmed separately to access different types of devices. The general-purpose chip select machine (GPCM) controls accesses to asynchronous devices using a simple handshake protocol. The three user programmable machines (UPMs) can be programmed to interface to synchronous devices or custom ASIC interfaces. Each chip select can be configured so that the associated chip interface can be controlled by the GPCM or UPM controller. The FCM provides a glueless interface to parallel-bus NAND Flash E2PROM devices. The FCM contains three basic configuration register groups—BRn, ORn, and FMR. Both may exist in the same system. The local bus can operate at up to 66 MHz.

The MPC8313E system timers include the following features: periodic interrupt timer, real time clock, software watchdog timer, and two general-purpose timer blocks.

2 Electrical Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC8313E. The MPC8313E is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

2.1 Overall DC Electrical Characteristics

This section covers the ratings, conditions, and other characteristics.

2.1.1 Absolute Maximum Ratings

Table 1 provides the absolute maximum ratings.

Table 1. Absolute Maximum Ratings ¹

| Characteristic | | Symbol | Max Value | Unit | Notes |
|--|--|--------------------------------------|--|------|-------|
| Core supply voltage | | V _{DD} | -0.3 to 1.26 | V | |
| PLL supply vol | tage | AV _{DD} | -0.3 to 1.26 | V | |
| DDR and DDR2 DRAM I/O voltage | | GV _{DD} | -0.3 to 2.75 -0.3 to 1.98 | V | |
| PCI, local bus, DUART, system control and power management, I ² C, and JTAG I/O voltage | | NV _{DD} /LV _{DD} | -0.3 to 3.6 | V | |
| eTSEC, USB | | LV _{DDA} /LV _{DDB} | -0.3 to 3.6 | V | |
| Input voltage | DDR DRAM signals | MV _{IN} | -0.3 to (GV _{DD} + 0.3) | V | 2, 5 |
| | DDR DRAM reference | MV _{REF} | -0.3 to (GV _{DD} + 0.3) | V | 2, 5 |
| | Enhanced Three-speed Ethernet signals | LVin | -0.3 to (LV _{DDA} + 0.3) or -0.3 to (LV _{DDB} + 0.3) | V | 4, 5 |
| | Local bus, DUART, SYS_CLK_IN, system control, and power management, I ² C, and JTAG signals | OV _{IN} | -0.3 to (NV _{DD} + 0.3) | V | 3, 5 |
| | PCI | OV _{IN} | -0.3 to (NV _{DD} + 0.3) | V | 6 |

Electrical Characteristics

Table 1. Absolute Maximum Ratings ¹ (continued)

| Characteristic | Symbol | Max Value | Unit | Notes |
|---------------------------|-----------|------------|------|-------|
| Storage temperature range | T_{STG} | -55 to 150 | °C | |

Notes:

- 1. Functional and tested operating conditions are given in Table 2. Absolute maximum ratings are stress ratings only, and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
- 2. **Caution:** MV_{IN} must not exceed GV_{DD} by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- Caution: OV_{IN} must not exceed NV_{DD} by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- Caution: LV_{IN} must not exceed LV_{DDA}/LV_{DDB} by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- 5. $(L,M,O)V_{IN}$ and MV_{REF} may overshoot/undershoot to a voltage and for a maximum duration as shown in Figure 2.
- OV_{IN} on the PCI interface may overshoot/undershoot according to the PCI Electrical Specification for 3.3-V operation, as shown in Figure 3.

2.1.2 Power Supply Voltage Specification

Table 2 provides the recommended operating conditions for the MPC8313E. Note that the values in Table 2 are the recommended and tested operating conditions. Proper device operation outside of these conditions is not guaranteed.

Table 2. Recommended Operating Conditions

| Characteristic | Symbol | Recommended Value ¹ | Unit | Current requirement |
|---|------------------|-----------------------------------|------|---------------------|
| SerDes (Lynx) internal digital power | XCOREVDD | 1.0 | V | 100 mA |
| SerDes (Lynx) internal digital power | XCOREVSS | 0.0 | V | |
| SerDes (Lynx) I/O digital power | XPADVDD | 1.0 | V | 10mA |
| SerDes (Lynx) I/O digital power | XPADVSS | 0.0 | V | |
| SerDes (Lynx) analog power for PLL | SDAVDD | 1.0 | V | 10 mA |
| SerDes (Lynx) analog power for PLL | SDAVSS | 0.0 | V | |
| Dedicated 3.3 V analog power for USB PLL | USB_PLL_PWR3 | 3.3 | V | 2–3 mA |
| Dedicated 1.0 V analog power for USB PLL | USB_PLL_PWR1 | 1.0 | V | 2–3 mA |
| Dedicated analog ground for USB PLL | USB_PLL_GND | 0.0 | V | |
| Dedicated USB power for USB Bias circuit | USB_VDDA_BIAS | 3.3 | V | 4–5 mA |
| Dedicated USB ground for USB Bias circuit | USB_VSSA_BIAS | 0.0 | V | |
| Dedicated power for USB Transceiver | USB_VDDA | 3.3 | V | 75 mA |
| Dedicated ground for USB transceiver | USB_VSSA | 0.0 | V | |
| Core supply voltage | V _{DD} | 1.0 | V | 560 mA |
| Internal core logic constant power | V _{DDC} | 1.0 | V | 454 mA |

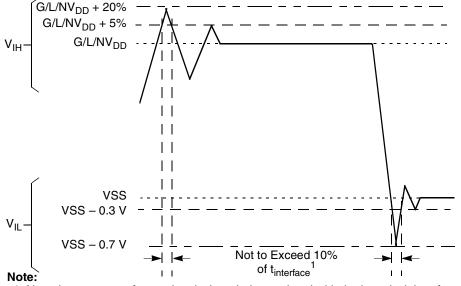
MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 2. Recommended Operating Conditions (continued)

| Characteristic | Symbol | Recommended Value ¹ | Unit | Current requirement |
|---|-------------------|-----------------------------------|------|---------------------|
| Analog power for e300 core APLL | AV _{DD1} | 1.0 | V | 10 mA |
| Analog power for system APLL | AV _{DD2} | 1.0 | V | 10 mA |
| DDR and DDR2 DRAM I/O voltage | GV _{DD} | 2.5/1.8 | V | 425 mA |
| Differential reference voltage for DDR controller | MV _{REF} | 1/2 DDR Supply | V | |
| Standard I/O Voltage | NV _{DD} | 3.3 | V | 27 mA |
| eTSEC2 IO Supply | LV _{DDA} | 2.5/3.3 | V | 85 mA |
| eTSEC1/USB DR IO Supply | LV _{DDB} | 2.5/3.3 | V | 85 mA |
| Supply for eLBCIOs | LV _{DD} | 3.3 | V | 60 mA |
| Analog and Digital Ground | VSS | 0.0 | V | |

Notes:

Figure 2 shows the undershoot and overshoot voltages at the interfaces of the MPC8313E.



1. Note that $t_{\mbox{\scriptsize interface}}$ refers to the clock period associated with the bus clock interface.

Figure 2. Overshoot/Undershoot Voltage for $GV_{DD}/NV_{DD}/LV_{DD}$

^{1.} GVDD, OVDD, AVDD, and VDD must track each other and must vary in the same direction—either in the positive or negative direction.

Electrical Characteristics

Figure 3 shows the undershoot and overshoot voltage of the PCI interface of the MPC8313E for the 3.3-V signals, respectively.

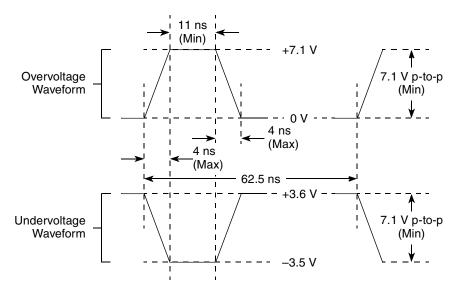


Figure 3. Maximum AC Waveforms on PCI Interface for 3.3-V Signaling

2.1.3 Output Driver Characteristics

Table 3 provides information on the characteristics of the output driver strengths. The values are preliminary estimates.

| Driver Type | Output Impedance (Ω) | Supply Voltage |
|---------------------------------------|----------------------|---|
| Local bus interface utilities signals | 42 | NV _{DD} = 3.3 V |
| PCI signals | 25 | |
| DDR signal | 18 | GV _{DD} = 2.5 V |
| DDR2 signal | 18 | GV _{DD} = 1.8 V |
| DUART, system control, I2C, JTAG,SPI | 42 | NV _{DD} = 3.3 V |
| GPIO signals | 42 | NV _{DD} = 3.3 V |
| eTSEC signals | 42 | LV _{DDA} , LV _{DDB} = 2.5/3.3 V |
| USB Signals | 42 | LV _{DDB} = 2.5/3.3 V |

Table 3. Output Drive Capability

2.2 Power Sequencing

The MPC8313E does not require the core supply voltage and IO supply voltages to be applied in any particular order. Note that during the power ramp-up, before the power supplies are stable, there might be a period when IO pins are actively driven. After the power is stable, as long as PORESET is asserted, most IO pins are tri-stated. In order to minimize the time that IO pins are being actively driven, it is

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

recommended to apply core voltage before IO voltage and assert PORESET before the power supplies fully ramp up.

3 Power Characteristics

The estimated typical power dissipation for this family of MPC8313E devices is shown in Table 4, and Table 5 shows the estimated typical I/O power dissipation.

Table 4. MPC8313E Power Dissipation ¹

| Core Frequency (MHz) | CSB Frequency (MHz) | Typical ^{2, 3} | Maximum ^{2,3} | Unit |
|----------------------|---------------------|-------------------------|------------------------|------|
| 267 | 133 | 680 | 880 | mW |
| 333 | 167 | 820 | 1020 | mW |

Note:

- 1. The values do not include I/O supply power or AV_{dd}.
- 2. Typical power is based on a voltage of $V_{dd} = 1.05V$, a junction temperature of $T_j = 105^{\circ}C$, and an artificial smoker test.
- 3. These are preliminary estimates

Table 5. MPC8313E Typical I/O Power Dissipation

| Interface | Parameter | GV _{DD} (1.8 V) | GV _{DD} (2.5 V) | NV _{DD} (3.3 V) | LV _{DDA} /LV _{DDB} (3.3V) | LV _{DDA} /LV _{DDB} (2.5V) | LV _{DDB} (3.3V) | Unit | Comments |
|---|-----------------|-----------------------------|-----------------------------|-----------------------------|---|--|-----------------------------|------|----------|
| DDR 1, 60% utilization, | 333MHz, 32 bits | _ | 0.355 | | | | | W | |
| 50% read/write Rs = 22Ω | 266MHz, 32 bits | _ | 0.323 | | | | | W | |
| Rt = 50Ω single pair of clock Capacitive Load: Data = 8pF, Control Address = 8pF, Clock = 8pF | 200MHz, 32 bits | _ | 0.291 | | | | | W | |
| DDR 2, 60% utilization, | 333MHz, 32 bits | 0.266 | _ | | | | | W | |
| 50% read/write Rs = 22Ω | 266MHz, 32 bits | 0.246 | _ | | | | | W | |
| Rt = 75Ω single pair of clock Capacitive Load: Data = 8pF, Control Address = 8pF, Clock = 8pF | 200MHz, 32bits | 0.225 | | | | | | W | |
| PCI I/O load = 50pF | 33 MHz | | | 0.120 | | | | W | |
| | 66 MHz | | | 0.249 | | | | W | |
| Local bus I/O | 66 MHz | | | 0.056 | | | | W | |
| load = 20pF | 50 MHz | | | 0.040 | | | | W | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Power Characteristics

Table 5. MPC8313E Typical I/O Power Dissipation (continued)

| TSEC I/O load = 20pF | MII, 25MHz | | | 0.008 | | | W | Multiple by |
|---------------------------------|---------------|--|-------|-------|-------|-------|---|--------------------------------|
| | RGMII, 125MHz | | | | 0.044 | | W | number of interface used |
| USBDR controller load = 20pF | 60 MHz | | | | | 0.078 | W | |
| Other I/O | | | 0.015 | | | | W | |

4 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8313E.

4.1 DC Electrical Characteristics

Table 6 provides the clock input (SYS_CLK_IN/PCI_SYNC_IN) DC timing specifications for the MPC8313E.

Symbol Parameter Condition Min Max Unit Input high voltage 2.7 $NV_{DD} + 0.3$ ٧ V_{IH} ٧ Input low voltage V_{II} -0.30.4 SYS_CLK_IN Input current $0 \text{ V } \leq V_{IN} \leq NV_{DD}$ ±10 μΑ I_{IN} PCI_SYNC_IN Input current 0 V \leq V_{IN} \leq 0.5 V or ±10 μΑ I_{IN} $NV_{DD} - 0.5 V \le V_{IN} \le NV_{DD}$ PCI_SYNC_IN Input current $0.5 \text{ V} \le \text{V}_{\text{IN}} \le \text{NV}_{\text{DD}} - 0.5 \text{ V}$ ±50 μΑ I_{IN}

Table 6. SYS CLK IN DC Electrical Characteristics

4.2 AC Electrical Characteristics

The primary clock source for the MPC8313E can be one of two inputs, SYS_CLK_IN or PCI_CLK, depending on whether the device is configured in PCI host or PCI agent mode. Table 7 provides the clock input (SYS_CLK_IN/PCI_CLK) AC timing specifications for the MPC8313E.

| Parameter/Condition | Symbol | Min | Typical | Max | Unit | Notes |
|---------------------------------------|---|-----|---------|------|------|-------|
| SYS_CLK_IN/PCI_CLK frequency | fsys_clk_in | 25 | _ | 66 | MHz | 1 |
| SYS_CLK_IN/PCI_CLK cycle time | tsys_clk_in | 15 | _ | _ | ns | _ |
| SYS_CLK_IN/PCI_CLK rise and fall time | t _{KH} , t _{KL} | 0.6 | 0.8 | 1.2 | ns | 2 |
| SYS_CLK_IN/PCI_CLK duty cycle | t _{KHK} /t _{SYS_CLK_IN} | 40 | _ | 60 | % | 3 |
| SYS_CLK_IN/PCI_CLK jitter | _ | _ | _ | ±150 | ps | 4, 5 |

Table 7. SYS_CLK_IN AC Timing Specifications

Notes:

- 1. Caution: The system, core, security block must not exceed their respective maximum or minimum operating frequencies.
- 2. Rise and fall times for SYS_CLK_IN/PCI_CLK are measured at 0.4 V and 2.7 V.
- 3. Timing is guaranteed by design and characterization.
- 4. This represents the total input jitter—short term and long term—and is guaranteed by design.
- 5. The SYS_CLK_IN/PCI_CLK driver's closed loop jitter bandwidth should be < 500 kHz at -20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track SYS_CLK_IN drivers with the specified jitter.

5 RESET Initialization

This section describes the DC and AC electrical specifications for the reset initialization timing and electrical requirements of the MPC8313E.

5.1 RESET DC Electrical Characteristics

Table 8 provides the DC electrical characteristics for the RESET pins.

Table 8. RESET Pins DC Electrical Characteristics

| Characteristic | Symbol | Condition | Min | Max | Unit |
|---------------------|-----------------|---|------|------------------------|------|
| Input high voltage | V _{IH} | | 2.0 | NV _{DD} + 0.3 | V |
| Input low voltage | V _{IL} | | -0.3 | 0.8 | V |
| Input current | I _{IN} | $0 \text{ V} \leq \text{ V}_{\text{IN}} \leq \text{NV}_{\text{DD}}$ | | ±5 | μΑ |
| Output high voltage | V _{OH} | $I_{OH} = -8.0 \text{ mA}$ | 2.4 | _ | V |
| Output low voltage | V _{OL} | I _{OL} = 8.0 mA | _ | 0.5 | V |
| Output low voltage | V _{OL} | I _{OL} = 3.2 mA | _ | 0.4 | V |

5.2 RESET AC Electrical Characteristics

Table 9 provides the reset initialization AC timing specifications.

Table 9. RESET Initialization Timing Specifications

| Parameter/Condition | Min | Max | Unit | Notes |
|---|-----|-----|--------------------------|-------|
| Required assertion time of HRESET or SRESET (input) to activate reset flow | 32 | _ | t _{PCI_SYNC_IN} | 1 |
| Required assertion time of PORESET with stable clock applied to SYS_CLK_IN when the device is in PCI host mode | 32 | _ | t _{SYS_CLK_IN} | 2 |
| Required assertion time of PORESET with stable clock applied to PCI_SYNC_IN when the device is in PCI agent mode | 32 | _ | t _{PCI_SYNC_IN} | 1 |
| HRESET/ SRESET assertion (output) | 512 | _ | t _{PCI_SYNC_IN} | 1 |
| HRESET negation to SRESET negation (output) | 16 | _ | t _{PCI_SYNC_IN} | 1 |
| Input setup time for POR configuration signals (CFG_RESET_SOURCE[0:3] and CFG_SYS_CLK_IN_DIV) with respect to negation of PORESET when the device is in PCI host mode | 4 | _ | tsys_clk_in | 2 |
| Input setup time for POR configuration signals (CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV) with respect to negation of PORESET when the device is in PCI agent mode | 4 | _ | t _{PCI_SYNC_IN} | 1 |
| Input hold time for POR configuration signals with respect to negation of HRESET | 0 | _ | ns | |

15

Table 9. RESET Initialization Timing Specifications (continued)

| Time for the device to turn off POR configuration signals with respect to the assertion of $\overline{\text{HRESET}}$ | _ | 4 | ns | 3 |
|---|---|---|--------------------------|------|
| Time for the device to turn on POR configuration signals with respect to the negation of HRESET | 1 | 1 | t _{PCI_SYNC_IN} | 1, 3 |

Notes:

- 1. t_{PCI_SYNC_IN} is the clock period of the input clock applied to PCI_SYNC_IN. When the device is In PCI host mode the primary clock is applied to the SYS_CLK_IN input, and PCI_SYNC_IN period depends on the value of CFG_CLKIN_DIV.
- 2. $t_{SYS\ CLK\ IN}$ is the clock period of the input clock applied to SYS_CLK_IN. It is only valid when the device is in PCI host mode.
- 3. POR configuration signals consists of CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV.

Table 10 provides the PLL lock times.

Table 10. PLL Lock Times

| Parameter/Condition | Min | Max | Unit | Notes |
|---------------------|-----|-----|------|-------|
| PLL lock times | _ | 100 | μs | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

6 DDR and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR SDRAM interface. Note that DDR SDRAM is $GV_{DD}(typ) = 2.5 \text{ V}$ and DDR2 SDRAM is $GV_{DD}(typ) = 1.8 \text{ V}$.

6.1 DDR and DDR2 SDRAM DC Electrical Characteristics

Table 11 provides the recommended operating conditions for the DDR2 SDRAM component(s) when $GV_{DD}(typ) = 1.8 \text{ V}$.

Table 11. DDR2 SDRAM DC Electrical Characteristics for GV_{DD}(typ) = 1.8 V

| Parameter/Condition | Symbol | Min | Мах | Unit | Notes |
|--|-------------------|-------------------------------------|-------------------------------------|------|-------|
| I/O supply voltage | GV _{DD} | 1.7 | 1.9 | V | 1 |
| I/O reference voltage | MV _{REF} | $0.49 \times \text{GV}_{\text{DD}}$ | $0.51 \times \text{GV}_{\text{DD}}$ | V | 2 |
| I/O termination voltage | V _{TT} | MV _{REF} - 0.04 | MV _{REF} + 0.04 | V | 3 |
| Input high voltage | V _{IH} | MV _{REF} + 0.125 | GV _{DD} + 0.3 | V | |
| Input low voltage | V _{IL} | -0.3 | MV _{REF} - 0.125 | V | |
| Output leakage current | I _{OZ} | -9.9 | 9.9 | μΑ | 4 |
| Output high current (V _{OUT} = 1.420 V) | I _{OH} | -13.4 | _ | mA | |
| Output low current (V _{OUT} = 0.280 V) | l _{OL} | 13.4 | _ | mA | |

Notes

- 1. GV_{DD} is expected to be within 50 mV of the DRAM GV_{DD} at all times.
- 2. MV_{REF} is expected to be equal to $0.5 \times GV_{DD}$, and to track GV_{DD} DC variations as measured at the receiver. Peak-to-peak noise on MV_{REF} may not exceed $\pm 2\%$ of the DC value.
- 3. V_{TT} is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to MV_{REF}. This rail should track variations in the DC level of MV_{REF}.
- 4. Output leakage is measured with all outputs disabled, 0 V \leq V_{OUT} \leq GV_{DD}.

Table 12 provides the DDR2 capacitance when $GV_{DD}(typ) = 1.8 \text{ V}$.

Table 12. DDR2 SDRAM Capacitance for GV_{DD}(typ)=1.8 V

| Parameter/Condition | Symbol | Min | Max | Unit | Notes |
|--|------------------|-----|-----|------|-------|
| Input/output capacitance: DQ, DQS, DQS | C _{IO} | 6 | 8 | pF | 1 |
| Delta input/output capacitance: DQ, DQS, DQS | C _{DIO} | _ | 0.5 | pF | 1 |

Note:

16

1. This parameter is sampled. $GV_{DD} = 1.8 \text{ V} \pm 0.090 \text{ V}$, f = 1 MHz, $T_A = 25^{\circ}\text{C}$, $V_{OUT} = GV_{DD}/2$, V_{OUT} (peak-to-peak) = 0.2 V.

Table 13 provides the recommended operating conditions for the DDR SDRAM component(s) when $GV_{DD}(typ) = 2.5 \text{ V}$.

Table 13. DDR SDRAM DC Electrical Characteristics for GV_{DD} (typ) = 2.5 V

| Parameter/Condition | Symbol | Min | Max | Unit | Notes |
|---|-------------------|-------------------------------------|-------------------------------------|------|-------|
| I/O supply voltage | GV _{DD} | 2.3 | 2.7 | V | 1 |
| I/O reference voltage | MV _{REF} | $0.49 \times \text{GV}_{\text{DD}}$ | $0.51 \times \text{GV}_{\text{DD}}$ | V | 2 |
| I/O termination voltage | V _{TT} | MV _{REF} - 0.04 | MV _{REF} + 0.04 | V | 3 |
| Input high voltage | V _{IH} | MV _{REF} + 0.15 | GV _{DD} + 0.3 | V | |
| Input low voltage | V _{IL} | -0.3 | MV _{REF} – 0.15 | V | |
| Output leakage current | I _{OZ} | -9.9 | -9.9 | μΑ | 4 |
| Output high current (V _{OUT} = 1.95 V) | Іон | -16.2 | _ | mA | |
| Output low current (V _{OUT} = 0.35 V) | I _{OL} | 16.2 | _ | mA | |

Notes:

- 1. ${\rm GV_{DD}}$ is expected to be within 50 mV of the DRAM ${\rm GV_{DD}}$ at all times.
- 2. MV_{REF} is expected to be equal to $0.5 \times GV_{DD}$, and to track GV_{DD} DC variations as measured at the receiver. Peak-to-peak noise on MV_{REF} may not exceed $\pm 2\%$ of the DC value.
- 3. V_{TT} is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to MV_{REF}. This rail should track variations in the DC level of MV_{REF}.
- 4. Output leakage is measured with all outputs disabled, 0 V \leq V_{OUT} \leq GV_{DD}.

Table 14 provides the DDR capacitance when GV_{DD} (typ)=2.5 V.

Table 14. DDR SDRAM Capacitance for GV_{DD} (typ) = 2.5 V

| Parameter/Condition | Symbol | Min | Max | Unit | Notes |
|---|------------------|-----|-----|------|-------|
| Input/output capacitance: DQ, DQS | C _{IO} | 6 | 8 | pF | 1 |
| Delta input/output capacitance: DQ, DQS | C _{DIO} | _ | 0.5 | pF | 1 |

Note:

1. This parameter is sampled. $GV_{DD} = 2.5 \text{ V} \pm 0.125 \text{ V}$, f = 1 MHz, $T_A = 25^{\circ}\text{C}$, $V_{OUT} = GV_{DD}/2$, V_{OUT} (peak-to-peak) = 0.2 V.

Table 15 provides the current draw characteristics for MV_{REF}.

Table 15. Current Draw Characteristics for MV_{REF}

| Parameter / Condition | Symbol | Min | Max | Unit | Note |
|------------------------------------|--------------------|-----|-----|------|------|
| Current draw for MV _{REF} | I _{MVREF} | | 500 | μА | 1 |

1. The voltage regulator for MV_{REF} must be able to supply up to 500 μ A current.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

6.2 DDR and DDR2 SDRAM AC Electrical Characteristics

This section provides the AC electrical characteristics for the DDR SDRAM interface.

DDR and DDR2 SDRAM Input AC Timing Specifications 6.2.1

Table 16 provides the input AC timing specifications for the DDR2 SDRAM when GV_{DD}(typ)=1.8 V.

Table 16. DDR2 SDRAM Input AC Timing Specifications for 1.8-V Interface

At recommended operating conditions with GV_{DD} of 1.8 ±5%

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------|-----------------|--------------------------|--------------------------|------|-------|
| AC input low voltage | V _{IL} | _ | MV _{REF} - 0.25 | V | |
| AC input high voltage | V _{IH} | MV _{REF} + 0.25 | _ | V | |

Table 17 provides the input AC timing specifications for the DDR SDRAM when $GV_{DD}(typ)=2.5 \text{ V}$.

Table 17. DDR SDRAM Input AC Timing Specifications for 2.5-V Interface

At recommended operating conditions with GV_{DD} of 2.5 ±5%.

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------|----------|--------------------------|--------------------------|------|-------|
| AC input low voltage | V_{IL} | _ | MV _{REF} – 0.31 | V | |
| AC input high voltage | V_{IH} | MV _{REF} + 0.31 | _ | V | |

Table 18 provides the input AC timing specifications for the DDR2 SDRAM interface.

Table 18. DDR and DDR2 SDRAM Input AC Timing Specifications

At recommended operating conditions, with GV_{DD} of 2.5 $\pm 5\%$

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------------------|---------------------|-------|------|------|-------|
| Controller Skew for MDQS—MDQ//MDM | ^t CISKEW | | | ps | 1, 2 |
| 333 MHz | | -750 | 750 | | |
| 266 MHz | | -750 | 750 | | |
| 200 MHz | | -1250 | 1250 | | |

- 1. t_{CISKEW} represents the total amount of skew consumed by the controller between MDQS[n] and any corresponding bit that will be captured with MDQS[n]. This should be subtracted from the total timing budget.
- 2. The amount of skew that can be tolerated from MDQS to a corresponding MDQ signal is called t_{DISKEW}. This can be determined by the following equation: $t_{DISKEW} = +/-(T/4 - abs(t_{CISKEW}))$ where T is the clock period and abs(t_{CISKEW}) is the absolute value of t_{CISKEW}.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications. Rev. 0 18 Freescale Semiconductor

6.2.2 DDR and DDR2 SDRAM Output AC Timing Specifications

Table 19. DDR and DDR2 SDRAM Output AC Timing Specifications

At recommended operating conditions.

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--|---|------|-----|------|-------|
| MCK[n] cycle time, MCK[n]/MCK[n] crossing | t _{MCK} | 6 | 10 | ns | 2 |
| ADDR/CMD output setup with respect to MCK | t _{DDKHAS} | | | ns | 3 |
| 333 MHz | | 2.1 | _ | | |
| 266 MHz | | 2.5 | _ | | |
| 200 MHz | | 3.5 | _ | | |
| ADDR/CMD output hold with respect to MCK | t _{DDKHAX} | | | ns | 3 |
| 333 MHz | | 2.40 | _ | | |
| 266 MHz | | 3.15 | _ | | |
| 200 MHz | | 4.20 | _ | | |
| MCS[n] output setup with respect to MCK | t _{DDKHCS} | | | ns | 3 |
| 333 MHz | | 2.40 | _ | | |
| 266 MHz | | 3.15 | _ | | |
| 200 MHz | | 4.20 | _ | | |
| MCS[n] output hold with respect to MCK | t _{DDKHCX} | | | ns | 3 |
| 333 MHz | | 2.40 | _ | | |
| 266 MHz | | 3.15 | _ | | |
| 200 MHz | | 4.20 | _ | | |
| MCK to MDQS Skew | t _{DDKHMH} | -0.6 | 0.6 | ns | 4 |
| MDQ//MDM output setup with respect to MDQS | t _{DDKHDS,} t _{DDKLDS} | | | ps | 5 |
| 333 MHz | | 800 | _ | | |
| 266 MHz | | 900 | _ | | |
| 200 MHz | | 1000 | _ | | |
| MDQ//MDM output hold with respect to MDQS | t _{DDKHDX,} t _{DDKLDX} | | | ps | 5 |
| 333 MHz | | 900 | _ | | |
| 266 MHz | | 1100 | _ | | |
| 200 MHz | | 1200 | _ | | |

Table 19. DDR and DDR2 SDRAM Output AC Timing Specifications (continued)

At recommended operating conditions.

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|---------------------|---------------------|-----------------------------|-----------------------------|------|-------|
| MDQS preamble start | t _{DDKHMP} | $-0.5 \times t_{MCK} - 0.6$ | $-0.5 \times t_{MCK} + 0.6$ | ns | 6 |
| MDQS epilogue end | ^t DDKHME | -0.6 | 0.6 | ns | 6 |

Note:

- 1. The symbols used for timing specifications follow the pattern of t_{(first two letters of functional block)(signal)(state)} for inputs and t_{(first two letters of functional block)(reference)(state)(signal)(state)} for outputs. Output hold time can be read as DDR timing (DD) from the rising or falling edge of the reference clock (KH or KL) until the output went invalid (AX or DX). For example, t_{DDKHAS} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes from the high (H) state until outputs (A) are setup (S) or output valid time. Also, t_{DDKLDX} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes low (L) until data outputs (D) are invalid (X) or data output hold time.
- 2. All MCK/MCK referenced measurements are made from the crossing of the two signals ±0.1 V.
- 3. ADDR/CMD includes all DDR SDRAM output signals except MCK/MCK, MCS, and MDQ//MDM/MDQS.
- 4. Note that t_{DDKHMH} follows the symbol conventions described in note 1. For example, t_{DDKHMH} describes the DDR timing (DD) from the rising edge of the MCK[n] clock (KH) until the MDQS signal is valid (MH). t_{DDKHMH} can be modified through control of the DQSS override bits in the TIMING_CFG_2 register. This will typically be set to the same delay as the clock adjust in the CLK_CNTL register. The timing parameters listed in the table assume that these 2 parameters have been set to the same adjustment value. See the MPC8313E PowerQUICC II Pro Host Processor Reference Manual for a description and understanding of the timing modifications enabled by use of these bits.
- 5. Determined by maximum possible skew between a data strobe (MDQS) and any corresponding bit of data (MDQ), ECC (MECC), or data mask (MDM). The data strobe should be centered inside of the data eye at the pins of the microprocessor.
- 6. All outputs are referenced to the rising edge of MCK[n] at the pins of the microprocessor. Note that t_{DDKHMP} follows the symbol conventions described in note 1.

NOTE

For the ADDR/CMD setup and hold specifications in Table 19, it is assumed that the clock control register is set to adjust the memory clocks by 1/2 applied cycle.

Figure 4 shows the DDR SDRAM output timing for the MCK to MDQS skew measurement (t_{DDKHMH}).

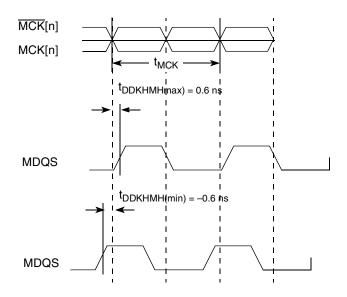


Figure 4. Timing Diagram for t_{DDKHMH}

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications. Rev. 0

Figure 5 shows the DDR and DDR2 SDRAM output timing diagram.

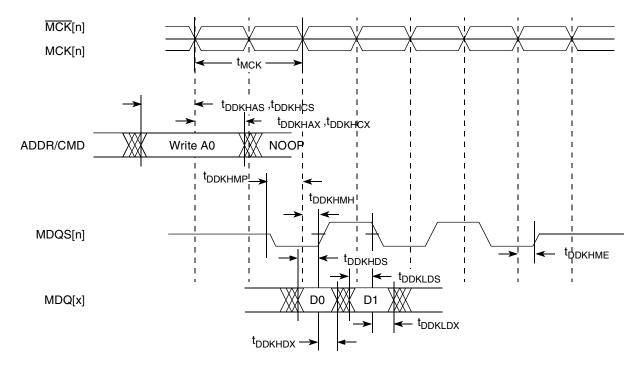


Figure 5. DDR and DDR2 SDRAM Output Timing Diagram

Figure 6 provides the AC test load for the DDR bus.

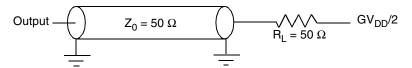


Figure 6. DDR AC Test Load

7 DUART

This section describes the DC and AC electrical specifications for the DUART interface.

7.1 DUART DC Electrical Characteristics

Table 20 provides the DC electrical characteristics for the DUART interface.

Table 20. DUART DC Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit |
|--|-----------------|------------------------|------------------------|------|
| High-level input voltage | V _{IH} | 2 | NV _{DD} + 0.3 | V |
| Low-level input voltage NVDD | V _{IL} | -0.3 | 0.8 | V |
| High-level output voltage, $I_{OH} = -100 \mu A$ | V _{OH} | NV _{DD} – 0.2 | _ | V |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 20. DUART DC Electrical Characteristics (continued)

| Low-level output voltage, $I_{OL} = 100 \mu A$ | V _{OL} | _ | 0.2 | V |
|--|-----------------|---|-----|----|
| Input current (0 $V \le V_{IN} \le NV_{DD}$) | I _{IN} | _ | ± 5 | μА |

7.2 DUART AC Electrical Specifications

Table 21 provides the AC timing parameters for the DUART interface.

Table 21. DUART AC Timing Specifications

| Parameter | Value | Unit | Notes |
|-------------------|-------------|------|-------|
| Minimum baud rate | 256 | baud | |
| Maximum baud rate | > 1,000,000 | baud | 1 |
| Oversample rate | 16 | _ | 2 |

Notes:

- 1. Actual attainable baud rate will be limited by the latency of interrupt processing.
- 2. The middle of a start bit is detected as the 8th sampled 0 after the 1-to-0 transition of the start bit. Subsequent bit values are sampled each 16th sample.

8 Ethernet: Three-Speed Ethernet, MII Management

This section provides the AC and DC electrical characteristics for three-speed, 10/100/1000, and MII management.

8.1 Enhanced Three-Speed Ethernet Controller (eTSEC) (10/100/1000 Mbps)—MII/RMII/RGMII/SGMII/RTBI Electrical Characteristics

The electrical characteristics specified here apply to all the MII (media independent interface), RGMII (reduced gigabit media independent interface), SGMII (serial gigabit media independent interface), and RTBI (reduced ten-bit interface) signals except MDIO (management data input/output) and MDC (management data clock). The MII interface is defined for 3.3V, while the RMII, RGMII, SGMII, and RTBI interfaces can be operated at 3.3 or 2.5 V. The RGMII and RTBI interfaces follow the Hewlett-Packard reduced pin-count interface for Gigabit Ethernet Physical Layer Device Specification Version 1.2a (9/22/2000). The electrical characteristics for MDIO and MDC are specified in Section 8.3, "Ethernet Management Interface Electrical Characteristics."

8.1.1 TSEC DC Electrical Characteristics

All RGMII, SGMII, RMII, and RTBI drivers and receivers comply with the DC parametric attributes specified in Table 22 and Table 23. The potential applied to the input of a MII, RGMII, SGMII, or RTBI receiver may exceed the potential of the receiver's power supply (that is, a RGMII driver powered from a 3.6-V supply driving V_{OH} into a RGMII receiver powered from a 2.5-V supply). Tolerance for dissimilar RGMII driver and receiver supply potentials is implicit in these specifications. The RGMII and RTBI signals are based on a 2.5-V CMOS interface voltage as defined by JEDEC EIA/JESD8-5.

| Parameter | Symbol | Conditions | | Min | Max | Unit |
|----------------------|--------------------------------------|---------------------------------------|--|------|--|----------|
| Supply voltage 3.3 V | LV _{DDA} /LV _{DDB} | | _ | 2.97 | 3.63 | V |
| Output high voltage | V _{OH} | $I_{OH} = -4.0 \text{ mA}$ | LV _{DDA} or LV _{DDB} = Min | 2.40 | LV _{DDA} + 0.3 or LV _{DDB} + 0.3 | V |
| Output low voltage | V _{OL} | I _{OL} = 4.0 mA | LV _{DDA} or LV _{DDB} = Min | VSS | 0.50 | V |
| Input high voltage | V _{IH} | _ | _ | 2.0 | LV _{DDA} + 0.3 or LV _{DDB} + 0.3 | V |
| Input low voltage | V _{IL} | _ | _ | -0.3 | 0.90 | V |
| Input high current | I _{IH} | $V_{IN}^{1} = LV_{DDA}$ or LV_{DDB} | | _ | 40 | μΑ |
| Input low current | I _{IL} | V _{II} | v 1 = VSS | -600 | _ | μΑ |

Table 22. MII/RGMII/RTBI (When Operating at 3.3V) DC Electrical Characteristics

Note:

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

^{1.} The symbol V_{IN} , in this case, represents the LV_{IN} symbol referenced in Table 1 and Table 2.

Ethernet: Three-Speed Ethernet, MII Management

| Parameters | Symbol | Conditions | | Min | Max | Unit |
|----------------------|--------------------------------------|---------------------------------------|--|-----------|--|------|
| Supply voltage 2.5 V | LV _{DDA} /LV _{DDB} | _ | | 2.37 | 2.63 | ٧ |
| Output high voltage | V _{OH} | $I_{OH} = -1.0 \text{ mA}$ | LV_{DDA} or $LV_{DDB} = Min$ | 2.00 | LV _{DDA} + 0.3 or LV _{DDB} + 0.3 | V |
| Output low voltage | V _{OL} | I _{OL} = 1.0 mA | LV _{DDA} or LV _{DDB} = Min | VSS - 0.3 | 0.40 | ٧ |
| Input high voltage | V _{IH} | _ | LV _{DDA} or LV _{DDB} = Min | 1.7 | LV _{DDA} + 0.3 or LV _{DDB} + 0.3 | V |
| Input low voltage | V _{IL} | _ | LV _{DDA} or LV _{DDB} = Min | -0.3 | 0.70 | V |
| Input high current | I _{IH} | $V_{IN}^{1} = LV_{DDA}$ or LV_{DDB} | | _ | 10 | μΑ |
| Input low current | I _{IL} | VI | N 1 = VSS | -15 | _ | μΑ |

Note:

8.2 MII, RGMII, SGMII, and RTBI AC Timing Specifications

The AC timing specifications for MII, RMII, RGMII, SGMII, and RTBI are presented in this section.

8.2.1 **MII AC Timing Specifications**

This section describes the MII transmit and receive AC timing specifications.

MII Transmit AC Timing Specifications 8.2.1.1

Table 24 provides the MII transmit AC timing specifications.

Table 24. MII Transmit AC Timing Specifications

At recommended operating conditions with LV $_{DDA}/LV_{DDB}/NV_{DD}$ of 3.3 V \pm 10%.

| Parameter/Condition | Symbol ¹ | Min | Тур | Max | Unit |
|---|-------------------------------------|-----|-----|-----|------|
| TX_CLK clock period 10 Mbps | t _{MTX} | _ | 400 | _ | ns |
| TX_CLK clock period 100 Mbps | t _{MTX} | _ | 40 | _ | ns |
| TX_CLK duty cycle | t _{MTXH} /t _{MTX} | 35 | _ | 65 | % |
| TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay | t _{MTKHDX} | 1 | 5 | 15 | ns |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0 24 Freescale Semiconductor

^{1.} Note that the symbol V_{IN} , in this case, represents the LV_{IN} symbol referenced in Table 1 and Table 2.

Table 24. MII Transmit AC Timing Specifications (continued)

At recommended operating conditions with LV_{DDA}/LV_{DDB} /NV_{DD} of 3.3 V ± 10%.

| Parameter/Condition | Symbol ¹ | Min | Тур | Max | Unit |
|---|---------------------|-----|-----|-----|------|
| TX_CLK data clock rise V _{IL} (min) to V _{IH} (max) | t _{MTXR} | 1.0 | _ | 4.0 | ns |
| TX_CLK data clock fall V _{IH} (max) to V _{IL} (min) | t _{MTXF} | 1.0 | 1 | 4.0 | ns |

Note:

1. The symbols used for timing specifications herein follow the pattern of t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{MTKHDX} symbolizes MII transmit timing (MT) for the time t_{MTX} clock reference (K) going high (H) until data outputs (D) are invalid (X). Note that, in general, the clock reference symbol representation is based on two to three letters representing the clock of a particular functional. For example, the subscript of t_{MTX} represents the MII(M) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 7 shows the MII transmit AC timing diagram.

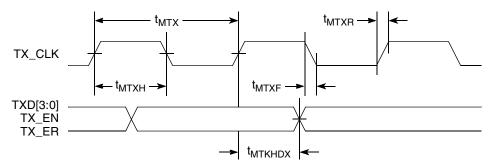


Figure 7. MII Transmit AC Timing Diagram

8.2.1.2 MII Receive AC Timing Specifications

Table 25 provides the MII receive AC timing specifications.

Table 25. MII Receive AC Timing Specifications

At recommended operating conditions with LV $_{\rm DDA}/{\rm LV}_{\rm DDB}$ /NV $_{\rm DD}$ of 3.3 V \pm 10%.

| Parameter/Condition | Symbol ¹ | Min | Тур | Max | Unit |
|---|-------------------------------------|------|-----|-----|------|
| RX_CLK clock period 10 Mbps | t _{MRX} | _ | 400 | _ | ns |
| RX_CLK clock period 100 Mbps | t _{MRX} | _ | 40 | _ | ns |
| RX_CLK duty cycle | t _{MRXH} /t _{MRX} | 35 | _ | 65 | % |
| RXD[3:0], RX_DV, RX_ER setup time to RX_CLK | t _{MRDVKH} | 10.0 | _ | _ | ns |
| RXD[3:0], RX_DV, RX_ER hold time to RX_CLK | t _{MRDXKH} | 10.0 | _ | _ | ns |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 25. MII Receive AC Timing Specifications (continued)

At recommended operating conditions with LV_{DDA}/LV_{DDB} /NV_{DD} of 3.3 V ± 10%.

| Parameter/Condition | Symbol ¹ | Min | Тур | Max | Unit |
|---|---------------------|-----|-----|-----|------|
| RX_CLK clock rise V _{IL} (min) to V _{IH} (max) | t _{MRXR} | 1.0 | _ | 4.0 | ns |
| RX_CLK clock fall time V _{IH} (max) to V _{IL} (min) | t _{MRXF} | 1.0 | 1 | 4.0 | ns |

Note:

1. The symbols used for timing specifications herein follow the pattern of t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{MRDVKH} symbolizes MII receive timing (MR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MRX} clock reference (K) going to the high (H) state or setup time. Also, t_{MRDXKL} symbolizes MII receive timing (GR) with respect to the time data input signals (D) went invalid (X) relative to the t_{MRX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{MRX} represents the MII (M) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 8 provides the AC test load for TSEC.

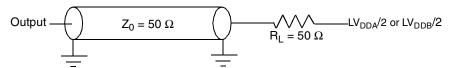


Figure 8. TSEC AC Test Load

Figure 9 shows the MII receive AC timing diagram.

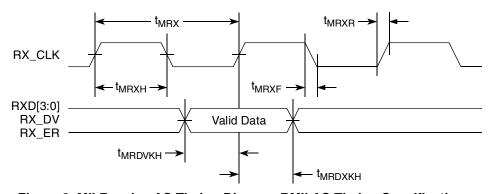


Figure 9. MII Receive AC Timing Diagram RMII AC Timing Specifications

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0 26 Freescale Semiconductor

8.2.1.3 RMII Transmit AC Timing Specifications

This section describes the RMII transmit and receive AC timing specifications.

Table 26 provides the RMII transmit AC timing specifications.

Table 26. RMII Transmit AC Timing Specifications

At recommended operating conditions with NV_{DD} of 3.3 V \pm 10%.

| Parameter/Condition | Symbol ¹ | Min | Typical | Max | Unit |
|--|-------------------------------------|-----|---------|-----|------|
| REF_CLK clock | t _{RMX} | _ | 20 | _ | ns |
| REF_CLK duty cycle | t _{RMXH} /t _{RMX} | 35 | _ | 65 | % |
| REF_CLK to RMII data TXD[1:0], TX_EN delay | t _{RMTKHDX} | 2 | - | 10 | ns |
| REF_CLK data clock rise V _{IL} (min) to V _{IH} (max) | t _{RMXR} | 1.0 | _ | 4.0 | ns |
| REF_CLK data clock fall V _{IH} (max) to V _{IL} (min) | t _{RMXF} | 1.0 | _ | 4.0 | ns |

Note:

1. The symbols used for timing specifications herein follow the pattern of t_{(first three letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{RMTKHDX} symbolizes RMII transmit timing (RMT) for the time t_{RMX} clock reference (K) going high (H) until data outputs (D) are invalid (X). Note that, in general, the clock reference symbol representation is based on two to three letters representing the clock of a particular functional. For example, the subscript of t_{RMX} represents the RMII(RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 10 shows the RMII transmit AC timing diagram.

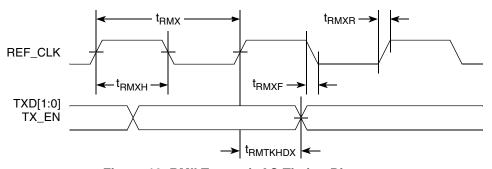


Figure 10. RMII Transmit AC Timing Diagram

8.2.1.4 RMII Receive AC Timing Specifications

Table 27 provides the RMII receive AC timing specifications.

Table 27. RMII Receive AC Timing Specifications

At recommended operating conditions with NV $_{DD}$ of 3.3 V \pm 10%.

| Parameter/Condition | Symbol ¹ | Min | Typical | Max | Unit |
|---|-------------------------------------|-----|---------|-----|------|
| REF_CLK clock period | t _{RMX} | _ | 20 | _ | ns |
| REF_CLK duty cycle | t _{RMXH} /t _{RMX} | 35 | _ | 65 | % |
| RXD[1:0], CRS_DV, RX_ER setup time to REF_CLK | t _{RMRDVKH} | 4.0 | _ | _ | ns |
| RXD[1:0], CRS_DV, RX_ER hold time to REF_CLK | t _{RMRDXKH} | 2.0 | _ | _ | ns |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 27. RMII Receive AC Timing Specifications (continued)

At recommended operating conditions with NV_{DD} of 3.3 V \pm 10%.

| Parameter/Condition | Symbol ¹ | Min | Typical | Max | Unit |
|--|---------------------|-----|---------|-----|------|
| REF_CLK clock rise V _{IL} (min) to V _{IH} (max) | t _{RMXR} | 1.0 | | 4.0 | ns |
| REF_CLK clock fall time V _{IH} (max) to V _{IL} (min) | t _{RMXF} | 1.0 | _ | 4.0 | ns |

Note:

1. The symbols used for timing specifications herein follow the pattern of t_{(first three letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{RMRDVKH} symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{RMX} clock reference (K) going to the high (H) state or setup time. Also, t_{RMRDXKL} symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) went invalid (X) relative to the t_{RMX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{RMX} represents the RMII (RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 11 provides the AC test load.

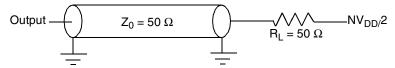


Figure 11. AC Test Load

Figure 12 shows the RMII receive AC timing diagram.

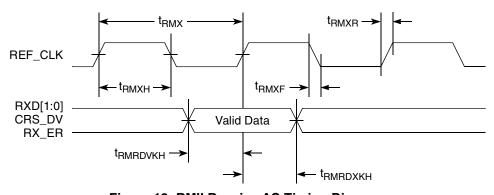


Figure 12. RMII Receive AC Timing Diagram

8.2.2 RGMII and RTBI AC Timing Specifications

Table 28 presents the RGMII and RTBI AC timing specifications.

Table 28. RGMII and RTBI AC Timing Specifications

At recommended operating conditions with LV $_{\rm DDA}/{\rm LV}_{\rm DDB}$ of 2.5 V \pm 5%.

| Parameter/Condition | Symbol ¹ | Min | Тур | Max | Unit |
|---|---------------------|------|-----|-----|------|
| Data to clock output skew (at transmitter) | t _{SKRGT} | -0.5 | _ | 0.5 | ns |
| Data to clock input skew (at receiver) ² | t _{SKRGT} | 1.0 | _ | 2.8 | ns |
| Clock cycle duration ³ | t _{RGT} | 7.2 | 8.0 | 8.8 | ns |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 28. RGMII and RTBI AC Timing Specifications (continued)

At recommended operating conditions with LV_{DDA}/LV_{DDB} of 2.5 V \pm 5%.

| Duty cycle for 1000Base-T ^{4, 5} | t _{RGTH} /t _{RGT} | 45 | 50 | 55 | % |
|---|---------------------------------------|----|-----|------|----|
| Duty cycle for 10BASE-T and 100BASE-TX 3, 5 | t _{RGTH} /t _{RGT} | 40 | 50 | 60 | % |
| Rise time (20%–80%) | t _{RGTR} | _ | _ | 0.75 | ns |
| Fall time (20%-80%) | t _{RGTF} | _ | _ | 0.75 | ns |
| GTX_CLK125 reference clock period | t _{G12} 6 | _ | 8.0 | _ | ns |
| GTX_CLK125 reference clock duty cycle | t _{G125H} /t _{G125} | 47 | _ | 53 | % |

Notes:

- 1. Note that, in general, the clock reference symbol representation for this section is based on the symbols RGT to represent RGMII and RTBI timing. For example, the subscript of t_{RGT} represents the RTBI (T) receive (RX) clock. Note also that the notation for rise (R) and fall (F) times follows the clock symbol that is being represented. For symbols representing skews, the subscript is skew (SK) followed by the clock that is being skewed (RGT).
- 2. This implies that PC board design will require clocks to be routed such that an additional trace delay of greater than 1.5 ns will be added to the associated clock signal.
- 3. For 10 and 100 Mbps, t_{RGT} scales to 400 ns \pm 40 ns and 40 ns \pm 4 ns, respectively.
- 4. Duty cycle may be stretched/shrunk during speed changes or while transitioning to a received packet's clock domains as long as the minimum duty cycle is not violated and stretching occurs for no more than three t_{RGT} of the lowest speed transitioned between.
- 5. Duty cycle reference is LV_{DDA}/2 or LV_{DDB}/2.
- 6. This symbol is used to represent the external GTX_CLK125 and does not follow the original symbol naming convention.

Figure 13 shows the RGMII and RTBI AC timing and multiplexing diagrams.

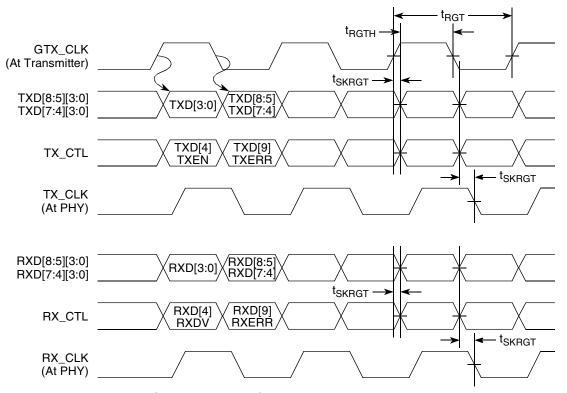


Figure 13. RGMII and RTBI AC Timing and Multiplexing Diagrams

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Ethernet: Three-Speed Ethernet, MII Management

8.3 Ethernet Management Interface Electrical Characteristics

The electrical characteristics specified here apply to MII management interface signals MDIO (management data input/output) and MDC (management data clock). The electrical characteristics for MII, RMII, RGMII, SGMII, and RTBI are specified in Section 8.1, "Enhanced Three-Speed Ethernet Controller (eTSEC) (10/100/1000 Mbps)—MII/RMII/RGMII/SGMII/RTBI Electrical Characteristics."

8.3.1 MII Management DC Electrical Characteristics

The MDC and MDIO are defined to operate at a supply voltage of 2.5V or 3.3 V. The DC electrical characteristics for MDIO and MDC are provided in Table 29 and Table 30.

Table 29. MII Management DC Electrical Characteristics When Powered at 2.5 V

| Parameter | Symbol | Conditions | | Min | Max | Unit |
|------------------------|--------------------------------------|---------------------------------------|--|-----------|--|------|
| Supply voltage (2.5 V) | NV _{DDA} /NV _{DDB} | | _ | 2.37 | 2.63 | V |
| Output high voltage | V _{OH} | $I_{OH} = -1.0 \text{ mA}$ | NV_{DDA} or $NV_{DDB} = Min$ | 2.00 | NV _{DDA} + 0.3 or NV _{DDB} + 0.3 | V |
| Output low voltage | V _{OL} | I _{OL} = 1.0 mA | NV_{DDA} or $NV_{DDB} = Min$ | VSS - 0.3 | 0.40 | V |
| Input high voltage | V _{IH} | _ | NV_{DDA} or $NV_{DDB} = Min$ | 1.7 | _ | V |
| Input low voltage | V _{IL} | _ | NV _{DDA} or NV _{DDB} = Min | -0.3 | 0.70 | V |
| Input high current | I _{IH} | $V_{IN}^{1} = NV_{DDA}$ or NV_{DDB} | | _ | 10 | μΑ |
| Input low current | I _{IL} | V _{IN} = N | V _{DDA} or NV _{DDB} | -15 | _ | μΑ |

Note:

Table 30. MII Management DC Electrical Characteristics When Powered at 3.3 V

| Parameter | Symbol | Condi | Min | Max | Unit | |
|------------------------|--------------------------------------|---|--|------|--|----|
| Supply voltage (3.3 V) | NV _{DDA} /NV _{DDB} | _ | 2.97 | 3.63 | V | |
| Output high voltage | V _{OH} | $I_{OH} = -1.0 \text{ mA}$ $NV_{DDA} \text{ or } NV_{DDB} = \text{Min}$ | | 2.10 | NV _{DDA} + 0.3 or NV _{DDB} + 0.3 | V |
| Output low voltage | V _{OL} | I _{OL} = 1.0 mA | $I_{OL} = 1.0 \text{ mA}$ $LV_{DDA} \text{ or } LV_{DDB} = \text{Min}$ | | 0.50 | V |
| Input high voltage | V _{IH} | _ | - | 2.00 | _ | V |
| Input low voltage | V _{IL} | _ | - | _ | 0.80 | V |
| Input high current | I _{IH} | NV_{DDA} or $NV_{DDB} = Max$ $V_{IN}^{-1} = 2.1 \text{ V}$ | | _ | 40 | μΑ |
| Input low current | I _{IL} | NV_{DDA} or $NV_{DDB} = Max$ $V_{IN} = 0.5 V$ | | -600 | _ | μΑ |

Note:

^{1.} Note that the symbol V_{IN} , in this case, represents the LV_{IN} symbol referenced in Table 1 and Table 2.

^{1.} Note that the symbol V_{IN}, in this case, represents the LV_{IN} symbol referenced in Table 1 and Table 2.

8.3.2 MII Management AC Electrical Specifications

Table 31 provides the MII management AC timing specifications.

Table 31. MII Management AC Timing Specifications

At recommended operating conditions with LV_{DDA}/LV_{DDB} is 3.3 V \pm 10% or 2.5 V \pm 5%

| Parameter/Condition | Symbol ¹ | Min | Тур | Max | Unit | Notes |
|----------------------------|---------------------|-----|-----|-----|------|-------|
| MDC frequency | f _{MDC} | _ | 2.5 | _ | MHz | 2 |
| MDC period | t _{MDC} | _ | 400 | _ | ns | |
| MDC clock pulse width high | t _{MDCH} | 32 | _ | _ | ns | |
| MDC to MDIO delay | t _{MDKHDX} | 10 | _ | 170 | ns | |
| MDIO to MDC setup time | ^t MDDVKH | 5 | _ | _ | ns | |
| MDIO to MDC hold time | t _{MDDXKH} | 0 | _ | _ | ns | |
| MDC rise time | t _{MDCR} | _ | _ | 10 | ns | |
| MDC fall time | t _{MDHF} | _ | _ | 10 | ns | |

Notes:

Figure 14 shows the MII management AC timing diagram.

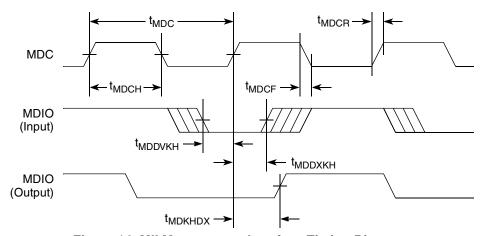


Figure 14. MII Management Interface Timing Diagram

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

^{1.} The symbols used for timing specifications herein follow the pattern of t_(first two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{MDKHDX} symbolizes management data timing (MD) for the time t_{MDC} from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, t_{MDDVKH} symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MDC} clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

SGMII DC Electrical Characteristics 8.3.3

The SGMII Solution in the MPC8313 is designed to be used in a 4-wire AC-Coupled SGMII link. Table 32 and Table 33 describe the SGMII AC-Coupled DC electrical characteristics. Transmitter characteristics are measured at the transmitter outputs, SD_TX and SD_TX_B as depicted in Figure 15.

Table 32. DC Transmitter Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------------------------|---------------------|--------------------------|------|------------------------------------|
| Output high voltage | V _{OH} | | 0.7*XPADVDD ¹ | mV | MCII o a a a li ana a a |
| Output low voltage | V _{OL} | 0.3*XPADVDD | | mV | Will not align to DC-coupled SGMII |
| Output ringing | V _{RING} | | 10 | % | |
| Output differential voltage | IV _{OD} I | (XPADVDD/2)/1.7 | (XPADVDD/2)/1.3 | mV | |
| Output offset voltage | V _{OS} | (XPADVDD/2) – 50 mV | (XPADVDD/2) + 50 mV | mV | Will not align to DC-coupled SGMII |
| Output impedance (single ended) | R _O | 40 | 60 | Ω | |
| Mismatch in a pair | ΔR_{O} | | 10 | % | |
| Change in V _{OD} between "0" and "1" | ΔIV _{OD} I | | 25 | mV | |
| Change in V _{OS} between "0" and "1" | ΔV _{OS} | | 25 | mV | |
| Output current on short to GND | I _{SA} , I _{SB} | | 40 | mA | |

¹ XPADVDDrefers to the SGMII transmitter output supply voltage.

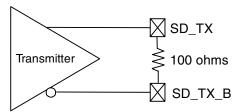


Figure 15. Transmitter Reference Circuit

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0 32 Freescale Semiconductor

Table 33. DC Receiver Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit | Notes |
|---------------------------------------|------------------|----------|----------|------|--|
| DC input voltage range | | | | | Input must be externally ac-coupled. |
| Input differential voltage | Vrx_diffpp | 100 | 1200 | mV | Peak to peak input differential voltage. |
| Loss of signal threshold | VI _{os} | 30 | 100 | mV | |
| Input AC common mode voltage | Vcm_acpp | | 100 | mV | Peak to peak ac common mode voltage. |
| Receiver differential input impedance | Zrx_diff | 80 | 120 | Ω | |
| Receiver common mode input impedance | Zrx_cm | 20 | 35 | Ω | |
| Common mode input voltage | Vcm | xcorevss | xcorevss | V | On-chip termination to xcorevss. |

8.3.3.1 SGMII Transmit AC Timing Specifications

Table 34 provides the SGMII transmit AC timing targets. A source synchronous clock is not provided.

Table 34. SGMII Transmit AC Timing Specifications

| Parameter | Symbol | Min | Max | Unit | Notes | | |
|---|-------------------|-----|------|--------|------------|--|--|
| Deterministic Jitter | J _D | | 0.17 | UI p-p | | | |
| Total Jitter | J _T | | 0.35 | UI p-p | | | |
| Unit Interval | U _I | 800 | 800 | ps | +/- 100ppm | | |
| V _{OD} fall time (80%–20%) | t _{fall} | 50 | 120 | ps | | | |
| V _{OD} rise time (20%–80%) | t _{rise} | 50 | 120 | ps | | | |
| Source synchronous clock is not supported | | | | | | | |

Ethernet: Three-Speed Ethernet, MII Management

8.3.3.2 SGMII Receive AC Timing Specifications

Table 35 provides the SGMII transmit AC timing targets. A source synchronous clock is not supported.

Table 35. SGMII Receiver AC Timing Specifications

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|------|-------------------|--------|----------------------|
| Deterministic Jitter Tolerance | J _D | 0.37 | | UI p-p | Measured at receiver |
| Combined Deterministic and Random Jitter Tolerance | J _{DR} | 0.55 | | UI p-p | Measured at receiver |
| Sinusoidal Jitter Tolerance | Jsin | 0.1 | | UI p-p | Measured at receiver |
| Total Jitter Tolerance | J _T | 0.65 | | UI p-p | Measured at receiver |
| Bit Error Ratio | BER | | 10 ⁻¹² | | |
| Unit Interval | UI | 800 | 800 | ps | +/- 100ppm |

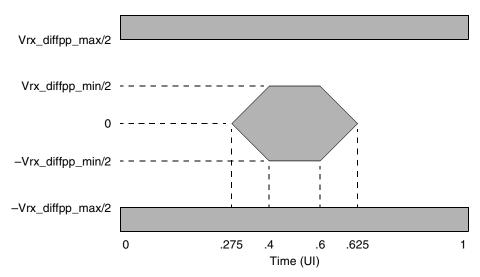


Figure 16. Receive Input Compliance Mask

35

9 USB

9.1 USB Dual-Role Controllers

This section provides the AC and DC electrical specifications for the USB interface.

9.1.1 USB DC Electrical Characteristics

Table 36 provides the DC electrical characteristics for the USB interface.

Table 36. USB DC Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit |
|---|-----------------|-------------------------|-------------------------|------|
| High-level input voltage | V _{IH} | 2 | LV _{DDB} + 0.3 | V |
| Low-level input voltage | V _{IL} | -0.3 | 0.8 | V |
| Input current | I _{IN} | _ | ±5 | μΑ |
| High-level output voltage, $I_{OH} = -100 \mu A$ | V _{OH} | LV _{DDB} – 0.2 | _ | V |
| Low-level output voltage, I _{OL} = 100 μA | V _{OL} | _ | 0.2 | V |

9.1.2 USB AC Electrical Specifications

Table 37 describes the general timing parameters of the USB interface.

Table 37. USB General Timing Parameters

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--|---------------------|-----|-----|------|-------|
| USB clock cycle time | tusck | 15 | _ | ns | |
| Input setup to USB clock - all inputs | t _{USIVKH} | 4 | _ | ns | |
| input hold to USB clock - all inputs | t _{USIXKH} | 0 | _ | ns | |
| USB clock to output valid - all outputs | t _{USKHOV} | _ | 7 | ns | |
| Output hold from USB clock - all outputs | tuskhox | 2 | _ | ns | |

Note:

^{1.} The symbols used for timing specifications herein follow the pattern of t_(First two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(First two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{USIXKH} symbolizes USB timing (USB) for the input (I) to go invalid (X) with respect to the time the USB clock reference (K) goes high (H). Also, t_{USKHOX} symbolizes us timing (USB) for the USB clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.

Figure 17 and Figure 18 provide the AC test load and signals for the USB, respectively.

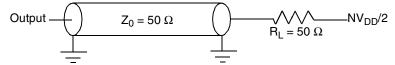


Figure 17. USB AC Test Load

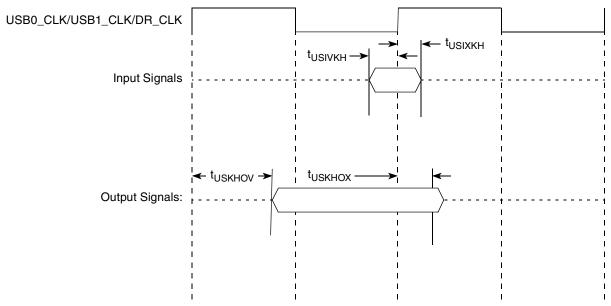


Figure 18. USB Signals

9.2 On-Chip USB PHY

See chapter 7 in the USB Specifications Rev 2.0

37

10 Local Bus

This section describes the DC and AC electrical specifications for the local bus interface.

10.1 Local Bus DC Electrical Characteristics

Table 38 provides the DC electrical characteristics for the local bus interface.

Table 38. Local Bus DC Electrical Characteristics at 3.3 V

| Parameter | Symbol | Min | Max | Unit |
|---|-----------------|------------------------|------------------------|------|
| High-level input voltage | V _{IH} | 2 | LV _{DD} + 0.3 | V |
| Low-level input voltage | V _{IL} | -0.3 | 0.8 | V |
| Input current $(V_{IN}^1 = 0 \text{ V or } V_{IN} = LV_{DD})$ | I _{IN} | _ | ±5 | μΑ |
| High-level output voltage, (LV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | LV _{DD} – 0.2 | _ | V |
| Low-level output voltage, (LV _{DD} = min, I _{OH} = 2 mA) | V _{OL} | _ | 0.2 | V |

10.2 Local Bus AC Electrical Specifications

Table 39 describes the general timing parameters of the local bus interface.

Table 39. Local Bus General Timing Parameters

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|---|----------------------|-----|-----|------|-------|
| Local bus cycle time | t _{LBK} | 15 | _ | ns | 2 |
| Input setup to local bus clock | t _{LBIVKH} | 7 | _ | ns | 3, 4 |
| Input hold from local bus clock | t _{LBIXKH} | 1.0 | _ | ns | 3, 4 |
| LALE output fall to LAD output transition (LATCH hold time) | t _{LBOTOT1} | 1.5 | _ | ns | 5 |
| LALE output fall to LAD output transition (LATCH hold time) | t _{LBOTOT2} | 3 | _ | ns | 6 |
| LALE output fall to LAD output transition (LATCH hold time) | t _{LBOTOT3} | 2.5 | _ | ns | 7 |

Table 39. Local Bus General Timing Parameters (continued)

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--|---------------------|-----|-----|------|-------|
| Local bus clock to output valid | t _{LBKHOV} | _ | 3 | ns | 3 |
| Local bus clock to output high impedance for LAD | t _{LBKHOZ} | _ | 4 | ns | 8 |

Notes:

- 1. The symbols used for timing specifications herein follow the pattern of t_(First two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(First two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{LBIXKH1} symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the t_{LBK} clock reference (K) goes high (H), in this case for clock one(1).
- 2. All timings are in reference to falling edge of LCLK0 (for all outputs and for LGTA and LUPWAIT inputs) or rising edge of LCLK0 (for all other inputs).
- 3. All signals are measured from NV_{DD}/2 of the rising/falling edge of LCLK0 to $0.4 \times NV_{DD}$ of the signal in question for 3.3-V signaling levels.
- 4. Input timings are measured at the pin.
- 5.t_{LBOTOT1} should be used when RCWH[LALE] is not set and the load on LALE output pin is at least 10pF less than the load on LAD output pins.
- 6.t_{LBOTOT2} should be used when RCWH[LALE] is set and the load on LALE output pin is at least 10pF less than the load on LAD output pins.
- 7.t_{LBOTOT3} should be used when RCWH[LALE] is set and the load on LALE output pin equals to the load on LAD output pins.
- 8. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.

Figure 19 provides the AC test load for the local bus.

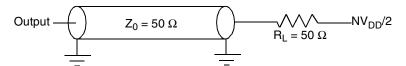


Figure 19. Local Bus AC Test Load

Figure 20 through Figure 22 show the local bus signals.

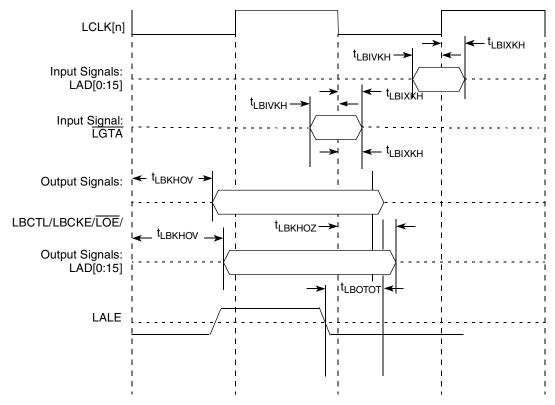


Figure 20. Local Bus Signals, Non-Special Signals Only

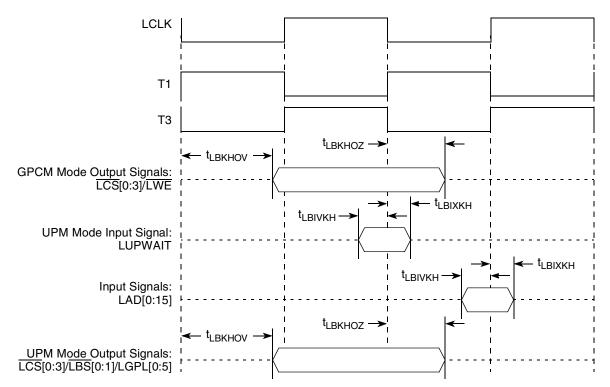


Figure 21. Local Bus Signals, GPCM/UPM Signals for LCCR[CLKDIV] = 2

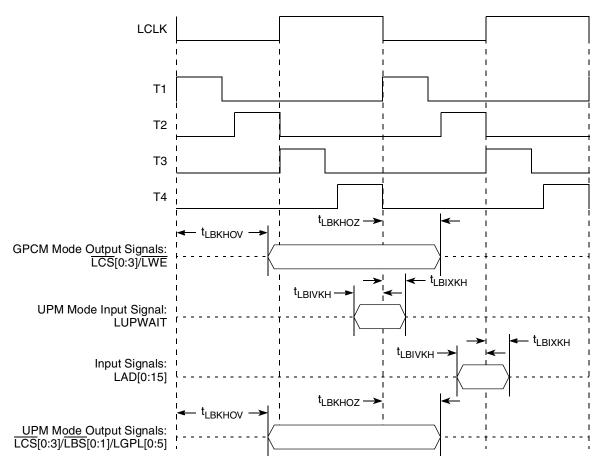


Figure 22. Local Bus Signals, GPCM/UPM Signals for LCCR[CLKDIV] = 4

11 JTAG

This section describes the DC and AC electrical specifications for the IEEE Std. 1149.1 (JTAG) interface.

11.1 JTAG DC Electrical Characteristics

Table 40 provides the DC electrical characteristics for the IEEE Std. 1149.1 (JTAG) interface.

Table 40. JTAG Interface DC Electrical Characteristics

| Characteristic | Symbol | Condition | Min | Max | Unit |
|---------------------|-----------------|----------------------------|------|------------------------|------|
| Input high voltage | V _{IH} | | 2.0 | NV _{DD} + 0.3 | V |
| Input low voltage | V _{IL} | | -0.3 | 0.8 | V |
| Input current | I _{IN} | | | ±5 | μΑ |
| Output high voltage | V _{OH} | $I_{OH} = -8.0 \text{ mA}$ | 2.4 | _ | V |
| Output low voltage | V _{OL} | I _{OL} = 8.0 mA | _ | 0.5 | V |
| Output low voltage | V _{OL} | I _{OL} = 3.2 mA | _ | 0.4 | V |

11.2 JTAG AC Timing Specifications

This section describes the AC electrical specifications for the IEEE Std. 1149.1 (JTAG) interface.

Table 41 provides the JTAG AC timing specifications as defined in Figure 24 through Figure 27.

Table 41. JTAG AC Timing Specifications (Independent of SYS_CLK_IN) ¹

At recommended operating conditions (see Table 2).

| Parameter | Symbol ² | Min | Max | Unit | Notes |
|---|--|----------|----------|------|-------|
| JTAG external clock frequency of operation | f _{JTG} | 0 | 33.3 | MHz | |
| JTAG external clock cycle time | t _{JTG} | 30 | _ | ns | |
| JTAG external clock pulse width measured at 1.4 V | t _{JTKHKL} | 15 | _ | ns | |
| JTAG external clock rise and fall times | t _{JTGR} & t _{JTGF} | 0 | 2 | ns | |
| TRST assert time | t _{TRST} | 25 | _ | ns | 3 |
| Input setup times: Boundary-scan data TMS, TDI | ^t JTDVКН ^t JTIVKH | 4 4 | | ns | 4 |
| Input hold times: Boundary-scan data TMS, TDI | ^t JTDXKH ^t JTIXKH | 10 10 | | ns | 4 |
| Valid times: Boundary-scan data TDO | t _{JTKLDV} t _{JTKLOV} | 2 2 | 11 11 | ns | 5 |
| Output hold times: Boundary-scan data TDO | t _{JTKLDX} t _{JTKLOX} | 2 2 | | ns | 5 |

Table 41. JTAG AC Timing Specifications (Independent of SYS_CLK_IN) 1 (continued)

At recommended operating conditions (see Table 2).

| Parameter | Symbol ² | Min | Max | Unit | Notes |
|---|--|--------|---------|------|-------|
| JTAG external clock to output high impedance: Boundary-scan data TDO | [†] JTKLDZ [†] JTKLOZ | 2 2 | 19 9 | ns | 5, 6 |

Notes:

- All outputs are measured from the midpoint voltage of the falling/rising edge of t_{TCLK} to the midpoint of the signal in question.
 The output timings are measured at the pins. All output timings assume a purely resistive 50-Ω load (see Figure 17).
 Time-of-flight delays must be added for trace lengths, vias, and connectors in the system.
- 2. The symbols used for timing specifications herein follow the pattern of t_(first two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{JTDVKH} symbolizes JTAG device timing (JT) with respect to the time data input signals (D) reaching the valid state (V) relative to the t_{JTG} clock reference (K) going to the high (H) state or setup time. Also, t_{JTDXKH} symbolizes JTAG timing (JT) with respect to the time data input signals (D) went invalid (X) relative to the t_{JTG} clock reference (K) going to the high (H) state. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- 3. TRST is an asynchronous level sensitive signal. The setup time is for test purposes only.
- 4. Non-JTAG signal input timing with respect to t_{TCLK}.
- 5. Non-JTAG signal output timing with respect to t_{TCLK}.
- 6. Guaranteed by design and characterization.

Figure 23 provides the AC test load for TDO and the boundary-scan outputs.

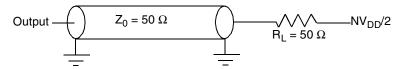


Figure 23. AC Test Load for the JTAG Interface

Figure 24 provides the JTAG clock input timing diagram.

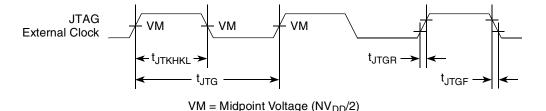


Figure 24. JTAG Clock Input Timing Diagram

Figure 25 provides the \overline{TRST} timing diagram.

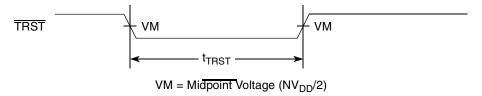
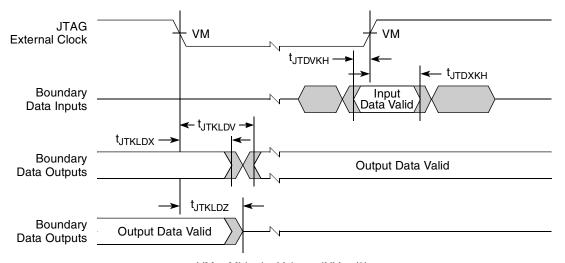


Figure 25. TRST Timing Diagram

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Figure 26 provides the boundary-scan timing diagram.



 $VM = Midpoint Voltage (NV_{DD}/2)$

Figure 26. Boundary-Scan Timing Diagram

Figure 27 provides the test access port timing diagram.

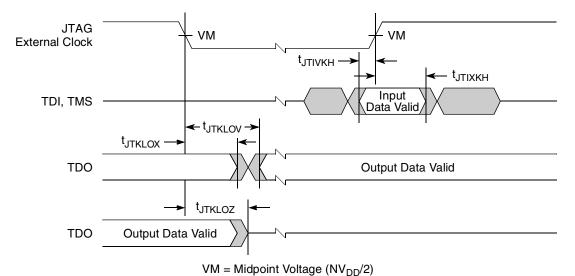


Figure 27. Test Access Port Timing Diagram

12 I²C

This section describes the DC and AC electrical characteristics for the I²C interface.

12.1 I²C DC Electrical Characteristics

Table 42 provides the DC electrical characteristics for the I²C interface.

Table 42. I²C DC Electrical Characteristics

At recommended operating conditions with NV_{DD} of 3.3 V \pm 10%.

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|---------------------|--------------------------------------|--------------------------------------|------|-------|
| Input high voltage level | V _{IH} | $0.7 \times \mathrm{NV}_\mathrm{DD}$ | NV _{DD} + 0.3 | V | |
| Input low voltage level | V _{IL} | -0.3 | $0.3 \times \mathrm{NV}_\mathrm{DD}$ | V | |
| Low level output voltage | V _{OL} | 0 | $0.2 \times \mathrm{NV}_\mathrm{DD}$ | V | 1 |
| Output fall time from V _{IH} (min) to V _{IL} (max) with a bus capacitance from 10 to 400 pF | ^t I2KLKV | 20 + 0.1 × C _B | 250 | ns | 2 |
| Pulse width of spikes which must be suppressed by the input filter | t _{I2KHKL} | 0 | 50 | ns | 3 |
| Capacitance for each I/O pin | C _I | _ | 10 | pF | |
| Input current (0 $V \le V_{IN} \le NV_{DD}$) | I _{IN} | _ | ± 5 | μΑ | 4 |

Notes:

- 1. Output voltage (open drain or open collector) condition = 3 mA sink current.
- 2. C_B = capacitance of one bus line in pF.
- 3. Refer to the MPC8313E PowerQUICC II Pro Integrated Host Processor Reference Manual for information on the digital filter used
- 4. I/O pins will obstruct the SDA and SCL lines if ${
 m NV}_{
 m DD}$ is switched off.

12.2 I²C AC Electrical Specifications

Table 43 provides the AC timing parameters for the I²C interface.

Table 43. I²C AC Electrical Specifications

All values refer to V_{IH} (min) and V_{IL} (max) levels (see Table 42).

| Parameter | Symbol ¹ | Min | Max | Unit |
|--|---------------------|-----|-----|------|
| SCL clock frequency | f _{I2C} | 0 | 400 | kHz |
| Low period of the SCL clock | t _{I2CL} | 1.3 | _ | μs |
| High period of the SCL clock | t _{I2CH} | 0.6 | _ | μs |
| Setup time for a repeated START condition | t _{I2SVKH} | 0.6 | _ | μs |
| Hold time (repeated) START condition (after this period, the first clock pulse is generated) | t _{I2SXKL} | 0.6 | _ | μs |
| Data setup time | t _{I2DVKH} | 100 | _ | ns |

Table 43. I²C AC Electrical Specifications (continued)

All values refer to V_{IH} (min) and V_{IL} (max) levels (see Table 42).

| Parameter | Symbol ¹ | Min | Max | Unit |
|---|---------------------|--------------------------------------|------------------|------|
| Data hold time: CBUS compatible masters I ² C bus devices | t _{I2DXKL} | | 0.9 ³ | μѕ |
| Rise time of both SDA and SCL signals | | 20 + 0.1 C _B ⁴ | 300 | ns |
| Fall time of both SDA and SCL signals | t _{I2CF} | 20 + 0.1 C _B ⁴ | 300 | ns |
| Setup time for STOP condition | t _{I2PVKH} | 0.6 | _ | μs |
| Bus free time between a STOP and START condition | t _{I2KHDX} | 1.3 | _ | μs |
| Noise margin at the LOW level for each connected device (including hysteresis) | V_{NL} | $0.1 \times NV_{DD}$ | _ | V |
| Noise margin at the HIGH level for each connected device (including hysteresis) | V _{NH} | $0.2 \times \text{NV}_{\text{DD}}$ | _ | V |

Notes:

- 1. The symbols used for timing specifications herein follow the pattern of t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{I2DVKH} symbolizes I²C timing (I2) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time. Also, t_{I2SXKL} symbolizes I²C timing (I2) for the time that the data with respect to the start condition (S) went invalid (X) relative to the t_{I2C} clock reference (K) going to the low (L) state or hold time. Also, t_{I2PVKH} symbolizes I²C timing (I2) for the time that the data with respect to the stop condition (P) reaching the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- 2. The MPC8313E provides a hold time of at least 300 ns for the SDA signal (referred to the V_{IHmin} of the SCL signal) to bridge the undefined region of the falling edge of SCL.
- 3. The maximum t_{I2DVKH} has only to be met if the device does not stretch the LOW period (t_{I2CL}) of the SCL signal.
- 4. C_B = capacitance of one bus line in pF.

Figure 28 provides the AC test load for the I²C.

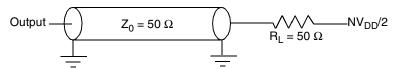


Figure 28. I²C AC Test Load

Figure 29 shows the AC timing diagram for the I^2C bus.

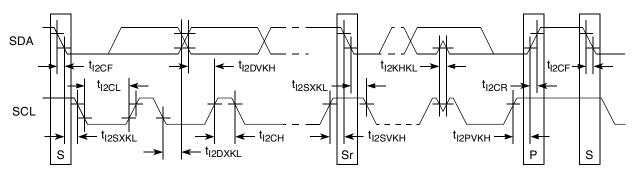


Figure 29. I²C Bus AC Timing Diagram

13 PCI

This section describes the DC and AC electrical specifications for the PCI bus.

13.1 PCI DC Electrical Characteristics

Table 44 provides the DC electrical characteristics for the PCI interface.

Table 44. PCI DC Electrical Characteristics ¹

| Parameter | Symbol | Test Condition | Min | Max | Unit |
|---------------------------|-----------------|---|------------------------|------------------------|------|
| High-level input voltage | V _{IH} | V _{OUT} ≥ V _{OH} (min) or | 0.5 x NV _{DD} | NV _{DD} + 0.3 | V |
| Low-level input voltage | V _{IL} | V _{OUT} ≤ V _{OL} (max) | -0.5 | 0.3 x NV _{DD} | V |
| High-level output voltage | V _{OH} | $NV_{DD} = min,$ $I_{OH} = -100 \mu A$ | 0.9 x NV _{DD} | _ | V |
| Low-level output voltage | V _{OL} | $NV_{DD} = min,$ $I_{OL} = 100 \mu A$ | _ | 0.1x NV _{DD} | V |
| Input current | I _{IN} | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ | _ | ± 5 | μА |

Note:

13.2 PCI AC Electrical Specifications

This section describes the general AC timing parameters of the PCI bus. Note that the PCI_CLK or PCI_SYNC_IN signal is used as the PCI input clock depending on whether the MPC8313E is configured as a host or agent device.

Table 45 shows the PCI AC timing specifications at 66 MHz.

Table 45. PCI AC Timing Specifications at 66 MHz

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--------------------------------|---------------------|-----|-----|------|-------|
| Clock to output valid | ^t PCKHOV | _ | 6.0 | ns | 2 |
| Output hold from Clock | t _{PCKHOX} | 1 | _ | ns | 2 |
| Clock to output high impedance | t _{PCKHOZ} | _ | 14 | ns | 2, 3 |
| Input setup to Clock | t _{PCIVKH} | 3.0 | _ | ns | 2, 4 |
| Input hold from Clock | t _{PCIXKH} | 0 | _ | ns | 2, 4 |

Notes:

- 1. Note that the symbols used for timing specifications herein follow the pattern of t_(first two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{PCIVKH} symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI_SYNC_IN clock, t_{SYS}, reference (K) going to the high (H) state or setup time. Also, t_{PCRHFV} symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
- 2. See the timing measurement conditions in the PCI 2.3 Local Bus Specifications.
- For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- 4. Input timings are measured at the pin.

^{1.} Note that the symbol V_{IN} , in this case, represents the OV_{IN} symbol referenced in Table 1 and Table 2.

Table 46 shows the PCI AC Timing Specifications at 33 MHz.

Table 46. PCI AC Timing Specifications at 33 MHz

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--------------------------------|---------------------|-----|-----|------|-------|
| Clock to output valid | t _{PCKHOV} | _ | 11 | ns | 2 |
| Output hold from Clock | t _{PCKHOX} | 2 | _ | ns | 2 |
| Clock to output high impedance | t _{PCKHOZ} | _ | 14 | ns | 2, 3 |
| Input setup to Clock | t _{PCIVKH} | 3.0 | _ | ns | 2, 4 |
| Input hold from Clock | t _{PCIXKH} | 0 | _ | ns | 2, 4 |

Notes:

- 1. Note that the symbols used for timing specifications herein follow the pattern of t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{PCIVKH} symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI_SYNC_IN clock, t_{SYS}, reference (K) going to the high (H) state or setup time. Also, t_{PCRHFV} symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
- 2. See the timing measurement conditions in the PCI 2.3 Local Bus Specifications.
- 3. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- 4. Input timings are measured at the pin.

Figure 30 provides the AC test load for PCI.

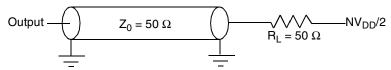


Figure 30. PCI AC Test Load

Figure 31 shows the PCI input AC timing conditions.

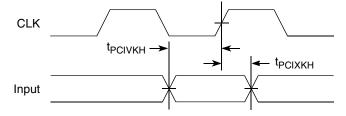


Figure 31. PCI Input AC Timing Measurement Conditions

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Figure 32 shows the PCI output AC timing conditions.

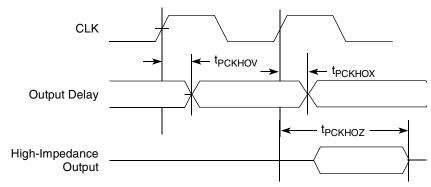


Figure 32. PCI Output AC Timing Measurement Condition

51

14 Timers

This section describes the DC and AC electrical specifications for the timers.

14.1 Timers DC Electrical Characteristics

Table 47 provides the DC electrical characteristics for the MPC8313E timers pins, including TIN, TOUT, TGATE, and RTC_CLK.

Characteristic Symbol Condition Min Max Unit Output high voltage V_{OH} $I_{OH} = -8.0 \text{ mA}$ 2.4 ٧ V_{OL} ٧ Output low voltage $I_{OL} = 8.0 \text{ mA}$ 0.5 $I_{OL} = 3.2 \text{ mA}$ Output low voltage V_{OL} ٧ Input high voltage $NV_{DD} + 0.3$ ٧ V_{IH} 2.0 ٧ -0.3Input low voltage V_{IL} 8.0 Input current $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ μΑ I_{IN} ± 5

Table 47. Timers DC Electrical Characteristics

14.2 Timers AC Timing Specifications

Table 48 provides the Timers input and output AC timing specifications.

Table 48. Timers Input AC Timing Specifications ¹

| Characteristic | Symbol ² | Min | Unit |
|-----------------------------------|---------------------|-----|------|
| Timers inputs—minimum pulse width | t _{TIWID} | 20 | ns |

Notes:

- 1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of SYS_CLK_IN. Timings are measured at the pin.
- 2. Timers inputs and outputs are asynchronous to any visible clock. Timers outputs should be synchronized before use by any external synchronous logic. Timers inputs are required to be valid for at least t_{TIWID} ns to ensure proper operation

Figure 33 provides the AC test load for the Timers.

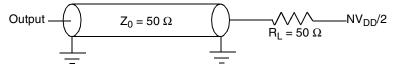


Figure 33. Timers AC Test Load

GPIO

15 GPIO

This section describes the DC and AC electrical specifications for the GPIO.

15.1 GPIO DC Electrical Characteristics

Table 49 provides the DC electrical characteristics for the GPIO.

Table 49. GPIO DC Electrical Characteristics

| Characteristic | Symbol | Condition | Min | Max | Unit |
|---------------------|-----------------|--|------|------------------------|------|
| Output high voltage | V _{OH} | $I_{OH} = -8.0 \text{ mA}$ | 2.4 | _ | V |
| Output low voltage | V _{OL} | I _{OL} = 8.0 mA | _ | 0.5 | V |
| Output low voltage | V _{OL} | I _{OL} = 3.2 mA | _ | 0.4 | V |
| Input high voltage | V _{IH} | _ | 2.0 | NV _{DD} + 0.3 | V |
| Input low voltage | V _{IL} | _ | -0.3 | 0.8 | V |
| Input current | I _{IN} | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ | _ | ± 5 | μΑ |

15.2 GPIO AC Timing Specifications

Table 50 provides the GPIO input and output AC timing specifications.

Table 50. GPIO Input AC Timing Specifications ¹

| Characteristic | Symbol ² | Min | Unit |
|---------------------------------|---------------------|-----|------|
| GPIO inputs—minimum pulse width | t _{PIWID} | 20 | ns |

Notes:

- 1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of SYS_CLKIN. Timings are measured at the pin.
- 2. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation.

Figure 34 provides the AC test load for the GPIO.

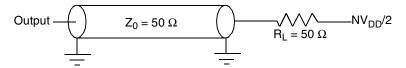


Figure 34. GPIO AC Test Load

16 IPIC

This section describes the DC and AC electrical specifications for the external interrupt pins.

16.1 IPIC DC Electrical Characteristics

Table 51 provides the DC electrical characteristics for the external interrupt pins.

Table 51. IPIC DC Electrical Characteristics

| Characteristic | Symbol | Condition | Min | Max | Unit |
|--------------------|-----------------|--------------------------|------|------------------------|------|
| Input high voltage | V _{IH} | | 2.0 | NV _{DD} + 0.3 | V |
| Input low voltage | V _{IL} | | -0.3 | 0.8 | V |
| Input current | I _{IN} | | | ±5 | μΑ |
| Output low voltage | V _{OL} | I _{OL} = 8.0 mA | _ | 0.5 | V |
| Output low voltage | V _{OL} | I _{OL} = 3.2 mA | _ | 0.4 | V |

16.2 IPIC AC Timing Specifications

Table 52 provides the IPIC input and output AC timing specifications.

Table 52. IPIC Input AC Timing Specifications ¹

| Characteristic | Symbol ² | Min | Unit |
|---------------------------------|---------------------|-----|------|
| IPIC inputs—minimum pulse width | t _{PIWID} | 20 | ns |

Notes:

- 1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of SYS_CLK_IN. Timings are measured at the pin.
- IPIC inputs and outputs are asynchronous to any visible clock. IPIC outputs should be synchronized before use by any
 external synchronous logic. IPIC inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation when working
 in edge triggered mode.

17 SPI

This section describes the DC and AC electrical specifications for the SPI of the MPC8313E

17.1 SPI DC Electrical Characteristics

Table 53 provides the DC electrical characteristics for the MPC8313E SPI.

Table 53. SPI DC Electrical Characteristics

| Characteristic | Symbol | Condition | Min | Max | Unit |
|---------------------|-----------------|--|------|------------------------|------|
| Output high voltage | V _{OH} | $I_{OH} = -6.0 \text{ mA}$ | 2.4 | _ | V |
| Output low voltage | V _{OL} | I _{OL} = 6.0 mA | _ | 0.5 | V |
| Output low voltage | V _{OL} | I _{OL} = 3.2 mA | _ | 0.4 | V |
| Input high voltage | V _{IH} | _ | 2.0 | OV _{DD} + 0.3 | ٧ |
| Input low voltage | V _{IL} | _ | -0.3 | 0.8 | ٧ |
| Input current | I _{IN} | $0 \text{ V} \leq V_{IN} \leq OV_{DD}$ | _ | ± 5 | μΑ |

17.2 SPI AC Timing Specifications

Table 54 and provide the SPI input and output AC timing specifications.

Table 54. SPI AC Timing Specifications ¹

| Characteristic | Symbol ² | Min | Max | Unit |
|--|---------------------|-----|-----|------|
| SPI outputs—Master mode (internal clock) delay | t _{NIKHOV} | 0.5 | 6 | ns |
| SPI outputs—Slave mode (external clock) delay | t _{NEKHOV} | 2 | 8 | ns |
| SPI inputs—Master mode (internal clock) input setup time | t _{NIIVKH} | 6 | | ns |
| SPI inputs—Master mode (internal clock) input hold time | t _{NIIXKH} | 0 | | ns |
| SPI inputs—Slave mode (external clock) input setup time | t _{NEIVKH} | 4 | | ns |
| SPI inputs—Slave mode (external clock) input hold time | t _{NEIXKH} | 2 | | ns |

Notes:

- 1. Output specifications are measured from the 50% level of the rising edge of SYS_CLK_IN to the 50% level of the signal. Timings are measured at the pin.
- 2. The symbols used for timing specifications follow the pattern of t_(first two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{NIKHOV} symbolizes the NMSI outputs internal timing (NI) for the time t_{SPI} memory clock reference (K) goes from the high state (H) until outputs (O) are valid (V).

Figure 35 provides the AC test load for the SPI.

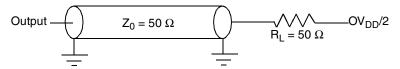
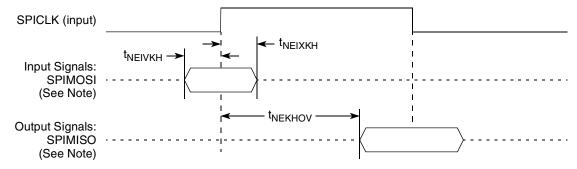


Figure 35. SPI AC Test Load

Figure 36 through Figure 37 represent the AC timing from Table 54. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

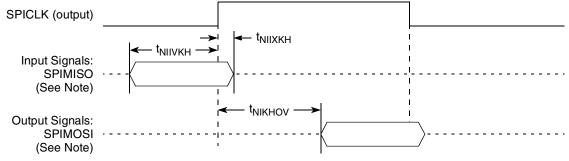
Figure 36 shows the SPI timing in Slave mode (external clock).



Note: The clock edge is selectable on SPI.

Figure 36. SPI AC Timing in Slave Mode (External Clock) Diagram

Figure 37 shows the SPI timing in Master mode (internal clock).



Note: The clock edge is selectable on SPI.

Figure 37. SPI AC Timing in Master Mode (Internal Clock) Diagram

18 Package and Pin Listings

This section details package parameters, pin assignments, and dimensions. The MPC8313E is available in a thermally enhanced plastic ball grid array (TEPBGAII), see Section 18.1, "Package Parameters for the MPC8313E TEPBGAII," and Section 18.2, "Mechanical Dimensions of the MPC8313E TEPBGAII," for information on the TEPBGAII.

18.1 Package Parameters for the MPC8313E TEPBGAII

The package parameters are as provided in the following list. The package type is $27 \text{ mm} \times 27 \text{ mm}$, 516 TEPBGAII.

Package outline $27 \text{ mm} \times 27 \text{ mm}$

Interconnects 516
Pitch 1.00 mm
Module height (typical) 2.25 mm

Solder Balls 95.5 Sn/0.5 Cu/4Ag (VR *package*)

Ball diameter (typical) 0.6 mm

18.2 Mechanical Dimensions of the MPC8313E TEPBGAII

Figure 38 shows the mechanical dimensions and bottom surface nomenclature of the 516-TEPBGAII package.

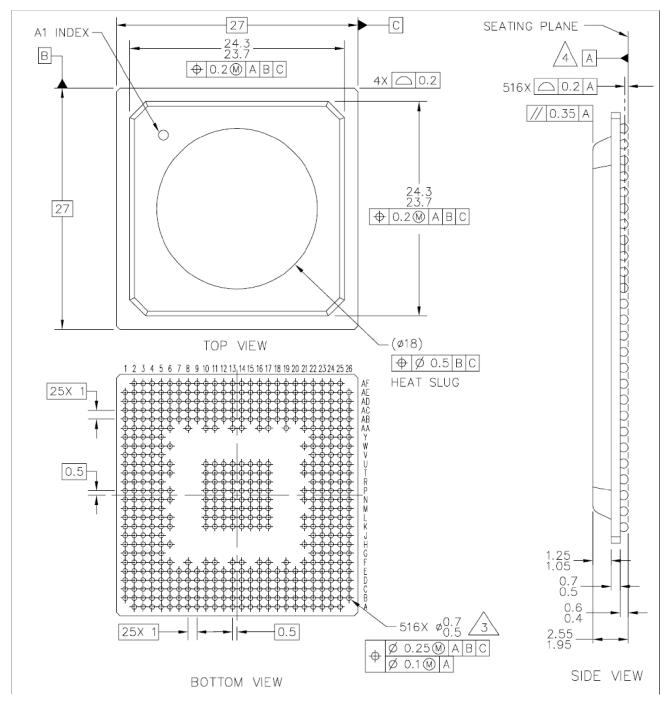


Figure 38. Mechanical Dimension and Bottom Surface Nomenclature of the MPC8313E TEPBGAII

- 1. All dimensions are in millimeters.
- 2. Dimensions and tolerances per ASME Y14.5M-1994.
- 3. Maximum solder ball diameter measured parallel to datum A.
- 4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
- 5. Package code 5368 is to account for PGE and the built–in heat spreader.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

18.3 Pinout Listings

Table 55 provides the pin-out listing for the MPC8313E, TEPBGAII package.

Table 55. MPC8313E TEPBGAll Pinout Listing

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------------|-----------------------------|----------|------------------|-------|
| DDR | Memory Controller Interface | | | |
| MEMC_MDQ[0] | A8 | Ю | GV _{DD} | |
| MEMC_MDQ[1] | A9 | Ю | GV _{DD} | |
| MEMC_MDQ[2] | C10 | Ю | GV _{DD} | |
| MEMC_MDQ[3] | C9 | Ю | GV _{DD} | |
| MEMC_MDQ[4] | E9 | Ю | GV _{DD} | |
| MEMC_MDQ[5] | E11 | Ю | GV _{DD} | |
| MEMC_MDQ[6] | E10 | Ю | GV _{DD} | |
| MEMC_MDQ[7] | C8 | Ю | GV _{DD} | |
| MEMC_MDQ[8] | E8 | Ю | GV _{DD} | |
| MEMC_MDQ[9] | A6 | Ю | GV _{DD} | |
| MEMC_MDQ[10] | B6 | Ю | GV _{DD} | |
| MEMC_MDQ[11] | C6 | Ю | GV _{DD} | |
| MEMC_MDQ[12] | C7 | Ю | GV _{DD} | |
| MEMC_MDQ[13] | D7 | Ю | GV _{DD} | |
| MEMC_MDQ[14] | D6 | Ю | GV _{DD} | |
| MEMC_MDQ[15] | A5 | Ю | GV _{DD} | |
| MEMC_MDQ[16] | A19 | Ю | GV _{DD} | |
| MEMC_MDQ[17] | D18 | Ю | GV _{DD} | |
| MEMC_MDQ[18] | A17 | Ю | GV _{DD} | |
| MEMC_MDQ[19] | E17 | Ю | GV _{DD} | |
| MEMC_MDQ[20] | E16 | Ю | GV _{DD} | |
| MEMC_MDQ[21] | C18 | Ю | GV _{DD} | |
| MEMC_MDQ[22] | D19 | Ю | GV _{DD} | |
| MEMC_MDQ[23] | C19 | Ю | GV _{DD} | |
| MEMC_MDQ[24] | E19 | Ю | GV _{DD} | |
| MEMC_MDQ[25] | A22 | Ю | GV _{DD} | |
| MEMC_MDQ[26] | C21 | Ю | GV _{DD} | |
| MEMC_MDQ[27] | C20 | Ю | GV _{DD} | |
| MEMC_MDQ[28] | A21 | Ю | GV _{DD} | |
| MEMC_MDQ[29] | A20 | Ю | GV _{DD} | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------------|--------------------|----------|------------------|-------|
| MEMC_MDQ[30] | C22 | Ю | GV _{DD} | |
| MEMC_MDQ[31] | B22 | Ю | GV _{DD} | |
| MEMC_MDM0 | B7 | 0 | GV _{DD} | |
| MEMC_MDM1 | E6 | 0 | GV _{DD} | |
| MEMC_MDM2 | E18 | 0 | GV _{DD} | |
| MEMC_MDM3 | E20 | 0 | GV _{DD} | |
| MEMC_MDQS[0] | A7 | Ю | GV _{DD} | |
| MEMC_MDQS[1] | E7 | Ю | GV _{DD} | |
| MEMC_MDQS[2] | B19 | Ю | GV _{DD} | |
| MEMC_MDQS[3] | A23 | Ю | GV _{DD} | |
| MEMC_MBA[0] | D15 | 0 | GV _{DD} | |
| MEMC_MBA[1] | A18 | 0 | GV _{DD} | |
| MEMC_MBA[2] | A15 | 0 | GV _{DD} | |
| MEMC_MA0 | E12 | 0 | GV _{DD} | |
| MEMC_MA1 | D11 | 0 | GV _{DD} | |
| MEMC_MA2 | B11 | 0 | GV _{DD} | |
| MEMC_MA3 | A11 | 0 | GV _{DD} | |
| MEMC_MA4 | A12 | 0 | GV _{DD} | |
| MEMC_MA5 | E13 | 0 | GV _{DD} | |
| MEMC_MA6 | C12 | 0 | GV _{DD} | |
| MEMC_MA7 | E14 | 0 | GV _{DD} | |
| MEMC_MA8 | B15 | 0 | GV _{DD} | |
| MEMC_MA9 | C17 | 0 | GV _{DD} | |
| MEMC_MA10 | C13 | 0 | GV _{DD} | |
| MEMC_MA11 | A16 | 0 | GV _{DD} | |
| MEMC_MA12 | C15 | 0 | GV _{DD} | |
| MEMC_MA13 | C16 | 0 | GV _{DD} | |
| MEMC_MA14 | E15 | 0 | GV _{DD} | |
| MEMC_MWE | B18 | 0 | GV _{DD} | |
| MEMC_MRAS | C11 | 0 | GV _{DD} | |
| MEMC_MCAS | B10 | 0 | GV _{DD} | |
| MEMC_MCS[0] | D10 | 0 | GV _{DD} | |
| MEMC_MCS[1] | A10 | 0 | GV _{DD} | |
| MEMC_MCKE | B14 | 0 | GV _{DD} | 3 |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Package and Pin Listings

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------------|-------------------------|----------|------------------|-------|
| MEMC_MCK | A13 | 0 | GV _{DD} | |
| MEMC_MCK | A14 | 0 | GV _{DD} | |
| MEMC_MODT[0] | B23 | 0 | GV _{DD} | |
| MEMC_MODT[1] | C23 | 0 | GV _{DD} | |
| Local B | us Controller Interface | | | |
| LAD0 | K25 | Ю | LV _{DD} | |
| LAD1 | K24 | Ю | LV _{DD} | |
| LAD2 | K23 | Ю | LV _{DD} | |
| LAD3 | K22 | Ю | LV _{DD} | |
| LAD4 | J25 | Ю | LV _{DD} | |
| LAD5 | J24 | Ю | LV _{DD} | |
| LAD6 | J23 | Ю | LV _{DD} | |
| LAD7 | J22 | Ю | LV _{DD} | |
| LAD8 | H24 | Ю | LV _{DD} | |
| LAD9 | F26 | Ю | LV _{DD} | |
| LAD10 | G24 | Ю | LV _{DD} | |
| LAD11 | F25 | Ю | LV _{DD} | |
| LAD12 | E25 | Ю | LV _{DD} | |
| LAD13 | F24 | Ю | LV _{DD} | |
| LAD14 | G22 | Ю | LV _{DD} | |
| LAD15 | F23 | Ю | LV _{DD} | |
| LA16 | AC25 | 0 | LV _{DD} | |
| LA17 | AC26 | 0 | LV _{DD} | |
| LA18 | AB22 | 0 | LV _{DD} | |
| LA19 | AB23 | 0 | LV _{DD} | |
| LA20 | AB24 | 0 | LV _{DD} | |
| LA21 | AB25 | 0 | LV _{DD} | |
| LA22 | AB26 | 0 | LV _{DD} | |
| LA23 | E22 | 0 | LV _{DD} | |
| LA24 | E23 | 0 | LV _{DD} | |
| LA25 | D22 | 0 | LV _{DD} | |
| LCS[0] | D23 | 0 | LV _{DD} | |
| LCS[1] | J26 | 0 | LV _{DD} | |
| LCS[2] | F22 | 0 | LV _{DD} | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------------------------|--------------------|----------|------------------|-------|
| LCS[3] | D26 | 0 | LV _{DD} | |
| TWE[0] | E24 | 0 | LV _{DD} | |
| LWE[1] | H26 | 0 | LV _{DD} | |
| LBCTL | L22 | 0 | LV _{DD} | |
| LALE/M1LALE/M2LALE | E26 | 0 | LV _{DD} | |
| LGPL0 | AA23 | 0 | LV _{DD} | |
| LGPL1 | AA24 | 0 | LV _{DD} | |
| LGPL2 | AA25 | 0 | LV _{DD} | |
| LGPL3 | AA26 | 0 | LV _{DD} | |
| LGPL4 | Y22 | Ю | LV _{DD} | |
| LGPL5 | E21 | 0 | LV _{DD} | |
| LCLK0 | H22 | 0 | LV _{DD} | |
| LCLK1 | G26 | 0 | LV _{DD} | |
| LA0/GPIO[0] | AC24 | Ю | LV _{DD} | |
| LA1/GPIO[1] | Y24 | Ю | LV _{DD} | |
| LA2/GPIO[2] | Y26 | Ю | LV _{DD} | |
| LA3/GPIO[3] | W22 | Ю | LV _{DD} | |
| LA4/GPIO[4] | W24 | Ю | LV _{DD} | |
| LA5/GPIO[5] | W26 | Ю | LV _{DD} | |
| LA6/GPIO[6] | V22 | Ю | LV _{DD} | |
| LA7/GPIO[7] | V23 | Ю | LV _{DD} | |
| LA8/GPIO[13] | V24 | Ю | LV _{DD} | |
| LA9/GPIO[14] | V25 | Ю | LV _{DD} | |
| LA10 | V26 | 0 | LV _{DD} | |
| LA11 | U22 | 0 | LV _{DD} | |
| LA12 | AD24 | 0 | LV _{DD} | |
| LA13 | L25 | 0 | LV _{DD} | |
| LA14 | L24 | 0 | LV _{DD} | |
| LA15 | K26 | 0 | LV _{DD} | |
| | DUART | | | |
| UART_SOUT1/MSRCID0 | N2 | 0 | NV _{DD} | |
| UART_SIN1/MSRCID1 | M5 | Ю | NV _{DD} | |
| UART_CTS[1]/GPIO[8]/MSRCID2 | M1 | Ю | NV _{DD} | |
| UART_RTS[1]/GPIO[9]/MSRCID3 | K1 | Ю | NV _{DD} | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Package and Pin Listings

Table 55. MPC8313E TEPBGAll Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------------------|----------------------------|----------|------------------|----------|
| UART_SOUT2/MSRCID4 | M3 | 0 | NV _{DD} | |
| UART_SIN2/MDVAL | L1 | Ю | NV _{DD} | |
| UART_CTS[2] | L5 | Ю | NV _{DD} | |
| UART_RTS[2] | L3 | Ю | NV _{DD} | |
| | I ² C interface | | 1 | <u>I</u> |
| IIC1_SDA/CKSTOP_OUT | J4 | Ю | NV _{DD} | 2 |
| IIC1_SCL/CKSTOP_IN | J2 | Ю | NV _{DD} | 2 |
| IIC2_SDA/PMC_PWR_OK/GPIO[10] | J3 | Ю | NV_{DD} | 2 |
| IIC2_SCL/GPIO[11] | H5 | Ю | NV _{DD} | 2 |
| | Interrupts | | 1 | |
| MCP_OUT | G5 | 0 | NV _{DD} | 2 |
| ĪRQ[0]/MCP_IN | K5 | I | NV_{DD} | |
| ĪRQ[1] | K4 | I | NV _{DD} | |
| ĪRQ[2] | K2 | I | NV _{DD} | |
| ĪRQ[3] /CKSTOP_OUT | K3 | Ю | NV _{DD} | |
| IRQ[4]/ CKSTOP_IN/GPIO[12] | J1 | Ю | NV _{DD} | |
| | Configuration | | 1 | <u>I</u> |
| CFG_CLKIN_DIV | D5 | I | NV_{DD} | |
| EXT_PWR_CTRL | J5 | 0 | NV _{DD} | |
| CFG_LBIU_MUX_EN | R24 | I | NV _{DD} | |
| | JTAG | | 1 | |
| тск | E1 | I | NV _{DD} | |
| TDI | E2 | I | NV _{DD} | 4 |
| TDO | E3 | 0 | NV_{DD} | 3 |
| TMS | E4 | I | NV_{DD} | 4 |
| TRST | E5 | I | NV_{DD} | 4 |
| | TEST | | 1 | l . |
| TEST_MODE | F4 | I | NV _{DD} | 6 |
| | DEBUG | | | |
| QUIESCE | F5 | 0 | NV _{DD} | |
| | System Control | | | |
| HRESET | F2 | Ю | NV _{DD} | 1 |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes | |
|-------------------|--------------------|----------|------------------|-------|--|
| PORESET | F3 | 1 | NV_{DD} | | |
| SRESET | F1 | I | NV_{DD} | | |
| | Clocks | | | | |
| SYS_CR_CLK_IN | U26 | I | NV _{DD} | | |
| SYS_CR_CLK_OUT | U25 | 0 | NV _{DD} | | |
| SYS_CLK_IN | U23 | I | NV _{DD} | | |
| USB_CR_CLK_IN | T26 | I | NV_{DD} | | |
| USB_CR_CLK_OUT | R26 | 0 | NV _{DD} | | |
| USB_CLK_IN | T22 | I | NV _{DD} | | |
| PCI_SYNC_OUT | U24 | 0 | NV _{DD} | 3 | |
| RTC_PIT_CLOCK | R22 | I | NV _{DD} | | |
| PCI_SYNC_IN | T24 | I | NV_{DD} | | |
| | MISC | | 1 | | |
| AV _{DD1} | F14 | I | Double with Pad | | |
| AV_{DD2} | P21 | I | Double with Pad | | |
| | PCI | | | | |
| PCI_INTA | AF7 | 0 | NV _{DD} | | |
| PCI_RESET_OUT | AB11 | 0 | NV _{DD} | | |
| PCI_AD[0] | AB20 | Ю | NV _{DD} | | |
| PCI_AD[1] | AF23 | Ю | NV _{DD} | | |
| PCI_AD[2] | AF22 | Ю | NV _{DD} | | |
| PCI_AD[3] | AB19 | Ю | NV _{DD} | | |
| PCI_AD[4] | AE22 | Ю | NV _{DD} | | |
| PCI_AD[5] | AF21 | Ю | NV _{DD} | | |
| PCI_AD[6] | AD19 | Ю | NV _{DD} | | |
| PCI_AD[7] | AD20 | AD20 IO | | | |
| PCI_AD[8] | AC18 | AC18 IO | | | |
| PCI_AD[9] | AD18 | AD18 IO | | | |
| PCI_AD[10] | AB18 | AB18 IO | | | |
| PCI_AD[11] | AE19 IO | | NV _{DD} | | |
| PCI_AD[12] | AB17 | Ю | NV _{DD} | | |
| PCI_AD[13] | AE18 | Ю | NV_{DD} | | |

Package and Pin Listings

Table 55. MPC8313E TEPBGAll Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes | |
|---------------------|--------------------|--------------------------|------------------|-------|--|
| PCI_AD[14] | AD17 | Ю | NV _{DD} | | |
| PCI_AD[15] | AF19 | Ю | NV_{DD} | | |
| PCI_AD[16] | AB14 | Ю | NV_{DD} | | |
| PCI_AD[17] | AF15 | Ю | NV_{DD} | | |
| PCI_AD[18] | AD14 | Ю | NV_{DD} | | |
| PCI_AD[19] | AE14 | Ю | NV_{DD} | | |
| PCI_AD[20] | AF12 | Ю | NV_{DD} | | |
| PCI_AD[21] | AE11 | Ю | NV_{DD} | | |
| PCI_AD[22] | AD12 | Ю | NV_{DD} | | |
| PCI_AD[23] | AB13 | Ю | NV_{DD} | | |
| PCI_AD[24] | AF9 | Ю | NV_{DD} | | |
| PCI_AD[25] | AD11 | Ю | NV_{DD} | | |
| PCI_AD[26] | AE10 | Ю | NV_{DD} | | |
| PCI_AD[27] | AB12 | Ю | NV_{DD} | | |
| PCI_AD[28] | AD10 | Ю | NV_{DD} | | |
| PCI_AD[29] | AC10 | Ю | NV_{DD} | | |
| PCI_AD[30] | AF10 | Ю | NV_{DD} | | |
| PCI_AD[31] | AF8 | Ю | NV_{DD} | | |
| PCI_C/BE[0] | AC19 | Ю | NV_{DD} | | |
| PCI_C/BE[1] | AB15 | Ю | NV_{DD} | | |
| PCI_C/BE[2] | AF14 | Ю | NV_{DD} | | |
| PCI_C/BE[3] | AF11 | AF11 IO | | | |
| PCI_PAR | AD16 | Ю | NV_{DD} | | |
| PCI_FRAME | AF16 | Ю | NV_{DD} | 5 | |
| PCI_TRDY | AD13 | Ю | NV_{DD} | 5 | |
| PCI_IRDY | AC15 | Ю | NV_{DD} | 5 | |
| PCI_STOP | AF13 | Ю | NV_{DD} | 5 | |
| PCI_DEVSEL | AC14 | Ю | NV _{DD} | 5 | |
| PCI_IDSEL | AF20 | AF20 I | | | |
| PCI_SERR | AE15 | Ю | NV _{DD} | 5 | |
| PCI_PERR | AD15 | AD15 IO | | 5 | |
| PCI_REQ0 | AB10 | AB10 IO NV _{DD} | | | |
| PCI_REQ1/CPCI_HS_ES | AD9 | AD9 I NV _{DD} | | | |
| PCI_REQ2 | AD8 | I | NV _{DD} | | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--|--------------------|----------|-------------------|-------|
| PCI_GNT0 | AC11 | Ю | NV _{DD} | |
| PCI_GNT1/CPCI_HS_LED | AE7 | 0 | NV_{DD} | |
| PCI_GNT2/CPCI_HS_ENUM | AD7 | 0 | NV_{DD} | |
| M66EN | AD21 | I | NV_{DD} | |
| PCI_CLK0 | AF17 | 0 | NV_{DD} | |
| PCI_CLK1 | AB16 | 0 | NV_{DD} | |
| PCI_CLK2 | AF18 | 0 | NV_{DD} | |
| PCI_PME | AD22 | Ю | NV_{DD} | |
| ETSEC1/ | /_USBULPI | | | |
| TSEC1_COL/USBDR_TXDRXD0 | AD2 | Ю | LV _{DDB} | |
| TSEC1_CRS/USBDR_TXDRXD1 | AC3 | Ю | LV _{DDB} | |
| TSEC1_GTX_CLK/USBDR_TXDRXD2 | AF3 | Ю | LV _{DDB} | 3 |
| TSEC1_RX_CLK/USBDR_TXDRXD3 | AE3 | Ю | LV _{DDB} | |
| TSCE1_RX_DV/USBDR_TXDRXD4 | AD3 | Ю | LV _{DDB} | |
| TSEC1_RXD[3]/USBDR_TXDRXD5 | AC6 | Ю | LV _{DDB} | |
| TSEC1_RXD[2]/USBDR_TXDRXD6 | AF4 | Ю | LV _{DDB} | |
| TSEC1_RXD[1]/USBDR_TXDRXD7 | AB6 | Ю | LV _{DDB} | |
| TSEC1_RXD[0]/USBDR_NXT/TSEC_1588_TRIG1 | AB5 | I | LV _{DDB} | |
| TSEC1_RX_ER/USBDR_DIR/TESC_1588_TRIG2 | AD4 | I | LV _{DDB} | |
| TSEC1_TX_CLK/USBDR_CLK/TSEC_1588_CLK | AF5 | I | LV _{DDB} | |
| TSEC1_TXD[3]/TSEC_1588_GCLK | AE6 | 0 | LV _{DDB} | |
| TSEC1_TXD[2]/TSEC_1588_PP1 | AC7 | 0 | LV _{DDB} | |
| TSEC1_TXD[1]/TSEC_1588_PP2 | AD6 | 0 | LV _{DDB} | |
| TSEC1_TXD[0]/USBDR_STP/TSEC_1588_PP3 | AD5 | 0 | LV _{DDB} | |
| TSEC1_TX_EN/TSEC_1588_ALARM1 | AB7 | 0 | LV _{DDB} | |
| TSEC1_TX_ER/TSEC_1588_ALARM2 | AB8 | 0 | LV _{DDB} | |
| TSEC1_GTX_CLK125 | AE1 | I | LV _{DDB} | |
| TSEC1_MDC | AF6 | 0 | NV_{DD} | |
| TSEC1_MDIO | AB9 | Ю | NV_{DD} | 2 |
| ET | SEC2 | | | |
| TSEC2_COL/GTM1_TIN4/GTM2_TIN3/GPIO[15] | AB4 | Ю | LV _{DDA} | |
| TSEC2_CRS/GTM1_TGATE4/GTM2_TGATE3/GPIO[16] | AB3 | Ю | LV _{DDA} | |
| TSEC2_GTX_CLK/GTM1_TOUT4/GTM2_TOUT3/GPIO[17] | AC1 | Ю | LV _{DDA} | |
| TSEC2_RX_CLK/GTM1_TIN2/GTM2_TIN1/GPI0[18] | AC2 | Ю | LV _{DDA} | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Package and Pin Listings

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes | |
|--|--------------------|----------|-------------------|-------|--|
| TSCE2_RX_DV/GTM1_TGATE2/GTM2_TGATE1/GPIO[19] | AA3 | Ю | LV _{DDA} | | |
| TSEC2_RXD[3]/GPIO[20] | Y5 | Ю | LV _{DDA} | | |
| TSEC2_RXD[2]/GPIO[21] | AA4 | Ю | LV _{DDA} | | |
| TSEC2_RXD[1]/GPIO[22] | AB2 | Ю | LV _{DDA} | | |
| TSEC2_RXD[0]/GPIO[23] | AA5 | Ю | LV _{DDA} | | |
| TSEC2_RX_ER/GTM1_TOUT2/GTM2_TOUT1/GPIO[24] | AA2 | Ю | LV _{DDA} | | |
| TSEC2_TX_CLK/GPIO[25] | AB1 | Ю | LV _{DDA} | | |
| TSEC2_TXD[3]/CFG_RESET_SOURCE[0] | W3 | Ю | LV _{DDA} | | |
| TSEC2_TXD[2]/CFG_RESET_SOURCE[1] | Y1 | Ю | LV _{DDA} | | |
| TSEC2_TXD[1]/CFG_RESET_SOURCE[2] | W5 | Ю | LV _{DDA} | | |
| TSEC2_TXD[0]/CFG_RESET_SOURCE[3] | Y3 | Ю | LV _{DDA} | | |
| TSEC2_TX_EN/GPIO[26] | AA1 | Ю | LV _{DDA} | | |
| TSEC2_TX_ER/GPIO[27] | W1 | Ю | LV _{DDA} | | |
| SGMII PH | ΙΥ | | • | | |
| TXA | U3 | 0 | | | |
| TXA | V3 | 0 | | | |
| RXA | U1 | I | | | |
| RXA | V1 | l | | | |
| TXB | P4 | 0 | | | |
| TXB | N4 | 0 | | | |
| RXB | R1 | I | | | |
| RXB | P1 | I | | | |
| SD_IMP_CAL_RX | V5 | I | | | |
| SD_REF_CLK | T5 | I | | | |
| SD_REF_CLK | T4 | I | | | |
| SD_PLL_TPD | T2 | 0 | | | |
| SD_IMP_CAL_TX | N5 | I | | | |
| SDAVDD | R5 | Ю | | | |
| SD_PLL_TPA_ANA | R4 | 0 | | | |
| SDAVSS | R3 | Ю | | | |
| USB PHY | | | | | |
| USB_DP | P26 | Ю | | | |
| USB_DM | N26 | Ю | | | |
| USB_VBUS | P24 | Ю | | | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--|--|----------|------------------|-------|
| USB_TPA | L26 | Ю | | |
| USB_RBIAS | M24 | Ю | | |
| USB_PLL_PWR3 | M26 | Ю | | |
| USB_PLL_GND | N24 | Ю | | |
| USB_PLL_PWR1 | N25 | Ю | | |
| USB_VSSA_BIAS | M25 | Ю | | |
| USB_VDDA_BIAS | M22 | Ю | | |
| USB_VSSA | N22 | Ю | | |
| USB_VDDA | P22 | Ю | | |
| GTI | M/USB | | | |
| USBDR_DRIVE_VBUS/GTM1_TIN1/GTM2_TIN2 | AD23 | Ю | NV _{DD} | |
| USBDR_PWRFAULT/GTM1_TGATE1/GTM2_TGATE2 | AE23 | Ю | NV_{DD} | |
| USBDR_PCTL0/GTM1_TOUT1 | AC22 | 0 | NV _{DD} | |
| USBDR_PCTL1 | AB21 | 0 | NV_{DD} | |
| | SPI | | | |
| SPIMOSI/GTM1_TIN3/GTM2_TIN4/GPIO[28] | H1 | Ю | NV_{DD} | |
| SPIMISO/GTM1_TGATE3/GTM2_TGATE4/GPIO[29]/LDVAL | H3 | Ю | NV _{DD} | |
| SPICLK/GTM1_TOUT3/GPIO[30] | G1 | Ю | NV_{DD} | |
| SPISEL/GPIO[31] | G3 | Ю | NV_{DD} | |
| Power and G | round Supplies | | | |
| GV _{DD} | A2,A3,A4,A24,A25,B3, B4,B5,B12,B13,B20, B21,B24,B25,B26,D1, D2,D8,D9,D16,D17 | | | |
| LV _{DD} | D24,D25,G23,H23,R23, T23,W25,Y25, AA22,AC23 | | | |
| LV _{DDA} | W2,Y2 | | | |
| LV _{DDB} | AC8,AC9,AE4,AE5 | | | |
| MV _{REF} | C14,D14 | | | |
| NV _{DD} | G4,H4,L2,M2,AC16, AC17,AD25,AD26,AE12, AE13,AE20,AE21,AE24, AE25,AE26,AF24, AF25 | | | |

Package and Pin Listings

Table 55. MPC8313E TEPBGAII Pinout Listing (continued)

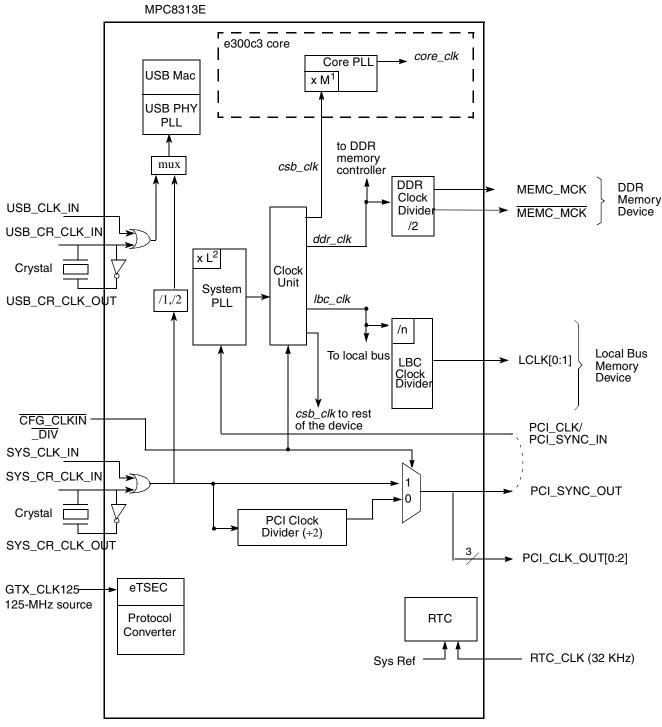
| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------|--|----------|-----------------|-------|
| V_{DD} | K11,K12,K13,K14,K15,K 16,L10,L17,M10,M17, N10,N17,U12,U13, T1,U2,V2,P5,U4 | | | |
| V _{DDC} | F6,F10,F19,K6,K10,K17, K21,P6,P10,P17,R10, R17,T10,T17,U10,U11, U14,U15,U16,U17,W6, W21,AA6,AA10,AA14, AA19 | | | |
| VSS | B1,B2,B8,B9,B16,B17, C1,C2,C3,C4,C5,C24, C25,C26,D3,D4,D12, D13,D20,D21,F8,F11, F13,F16,F17,F21,G2, G25,H2,H6,H21,H25, L4,L6,L11,L12,L13,L14, L15,L16,L21,L23,M4, M11,M12,M13,M14, M15,M16,M23,N1, N3,N6,N11,N12,N13, N14,N15,N16,N21,N23, P11,P12,P13,P14,P15, P16,P23,P25,R11,R12, R13,R14,R15,R16,R25, T6,T11,T12,T13,T14, T15,T16,T21,T25,U5, U6,U21,W4,W23,Y4, Y23,AA8,AA11,AA13, AA16,AA17,AA21,AC4, AC5,AC12,AC13,AC20, AC21,AD1,AE2,AE8, AE9,AE16,AE17,AF2, P2, R2,T3,P3,V4 | | | |

Notes:

- 1. This pin is an open drain signal. A weak pull-up resistor (1 $k\Omega$) should be placed on this pin to NV_{DD}
- 2. This pin is an open drain signal. A weak pull-up resistor (2–10 ${\rm k}\Omega$) should be placed on this pin to NV_{DD}.
- 3. This output is actively driven during reset rather than being three-stated during reset.
- 4. These JTAG pins have weak internal pull-up P-FETs that are always enabled.
- 5. This pin should have a weak pull up if the chip is in PCI host mode. Follow PCI specifications recommendation.
- 6. This pin must always be tied to VSS.

19 Clocking

Figure 39 shows the internal distribution of clocks within the MPC8313E.



¹ Multiplication factor M = 1, 1.5, 2, 2.5, and 3.

Figure 39. MPC8313E Clock Subsystem

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

² Multiplication factor L = 2, 3, 4, 5 and 6. Value is decided by RCWLR[SPMF].

Clocking

The primary clock source for the MPC8313E can be one of two inputs, SYS_CLK_IN or PCI_CLK, depending on whether the device is configured in PCI host or PCI agent mode. When the device is configured as a PCI host device, SYS_CLK_IN is its primary input clock. SYS_CLK_IN feeds the PCI clock divider (÷2) and the multiplexors for PCI_SYNC_OUT and PCI_CLK_OUT. The CFG_CLKIN_DIV configuration input selects whether SYS_CLK_IN or SYS_CLK_IN/2 is driven out on the PCI_SYNC_OUT signal. The OCCR[PCICOEn] parameters select whether the PCI_SYNC_OUT is driven out on the PCI_CLK_OUTn signals.

PCI_SYNC_OUT is connected externally to PCI_SYNC_IN to allow the internal clock subsystem to synchronize to the system PCI clocks. PCI_SYNC_OUT must be connected properly to PCI_SYNC_IN, with equal delay to all PCI agent devices in the system, to allow the device to function. When the device is configured as a PCI agent device, PCI_SYNC_IN is the primary input clock. When the device is configured as a PCI agent device the SYS_CLK_IN signal should be tied to VSS.

As shown in Figure 39, the primary clock input (frequency) is multiplied up by the system phase-locked loop (PLL) and the clock unit to create the coherent system bus clock (*csb_clk*), the internal clock for the DDR controller (*ddr_clk*), and the internal clock for the local bus interface unit (*lbc_clk*).

The *csb_clk* frequency is derived from a complex set of factors that can be simplified into the following equation:

$$csb$$
 $clk = \{PCI \ SYNC \ IN \times (1 + \sim \overline{CFG \ CLKIN \ DIV})\} \times SPMF$

In PCI host mode, PCI_SYNC_IN \times (1 + \sim CFG_CLKIN_DIV) is the SYS_CLK_IN frequency.

The *csb_clk* serves as the clock input to the e300 core. A second PLL inside the e300 core multiplies up the *csb_clk* frequency to create the internal clock for the e300 core (*core_clk*). The system and core PLL multipliers are selected by the SPMF and COREPLL fields in the reset configuration word low (RCWL) which is loaded at power-on reset or by one of the hard-coded reset options. See Chapter 4, "Reset, Clocking, and Initialization," in the *MPC8313E PowerQUICC II Pro Integrated Host Processor Reference Manual* for more information on the clock subsystem.

The internal $ddr_{-}clk$ frequency is determined by the following equation:

$$ddr_{c}lk = csb_{c}lk \times (1 + RCWL[DDRCM])$$

Note that ddr_clk is not the external memory bus frequency; ddr_clk passes through the DDR clock divider (÷2) to create the differential DDR memory bus clock outputs (MCK and $\overline{\text{MCK}}$). However, the data rate is the same frequency as ddr_clk .

The internal *lbc_clk* frequency is determined by the following equation:

$$lbc_clk = csb_clk \times (1 + RCWL[LBCM])$$

Note that *lbc_clk* is not the external local bus frequency; *lbc_clk* passes through the a LBC clock divider to create the external local bus clock outputs (LCLK[0:1]). The LBC clock divider ratio is controlled by LCCR[CLKDIV].

In addition, some of the internal units may be required to be shut off or operate at lower frequency than the *csb_clk* frequency. Those units have a default clock ratio that can be configured by a memory mapped register after the device comes out of reset. Table 56 specifies which units have a configurable clock frequency.

Table 56. Configurable Clock Units

| Unit | Default Frequency | Options |
|------------------------------|----------------------|--|
| TSEC1 | csb_clk | Off, csb_clk , csb_clk /2, csb_clk /3 |
| TSEC2 | csb_clk | Off, csb_clk, csb_clk/2, csb_clk/3 |
| Security Core, I2C, SAP, TPR | csb_clk | Off, csb_clk , $csb_clk/2$, $csb_clk/3$ |
| USB DR | csb_clk | Off, csb_clk, csb_clk/2, csb_clk/3 |
| PCI and DMA complex | csb_clk | Off, csb_clk |

Table 57 provides the operating frequencies for the MPC8313E TEPBGA II under recommended operating conditions (see Table 2).

Table 57. Operating Frequencies for TEPBGA II

| Characteristic ¹ | Max Operating Frequency | Unit |
|--|-------------------------|------|
| e300 core frequency (core_clk) | 333 | MHz |
| Coherent system bus frequency (csb_clk) | 167 | MHz |
| DDR1/2 memory bus frequency (MCK) ² | 167 | MHz |
| Local bus frequency (LCLKn) ³ | 33–66 | MHz |
| PCI input frequency (SYS_CLK_IN or PCI_CLK) | 24–66 | MHz |

Notes:

- 1. The SYS_CLK_IN frequency, RCWL[SPMF], and RCWL[COREPLL] settings must be chosen such that the resulting *csb_clk*, MCK, LCLK[0:1], and *core_clk* frequencies do not exceed their respective maximum or minimum operating frequencies. The value of SCCR[ENCCM] and SCCR[USBDRCM] must be programmed such that the maximum internal operating frequency of the Security core and USB modules will not exceed their respective value listed in this table.
- 2. The DDR data rate is 2x the DDR memory bus frequency.
- 3. The local bus frequency is 1/2, 1/4, or 1/8 of the *lbc_clk* frequency (depending on LCCR[CLKDIV]) which is in turn 1x or 2x the *csb_clk* frequency (depending on RCWL[LBCM]).

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Clocking

19.1 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] parameter. Table 58 shows the multiplication factor encodings for the system PLL.

 RCWL[SPMF]
 System PLL Multiplication Factor

 0000
 Reserved

 0001
 Reserved

 0010
 × 2

 0011
 × 3

 0100
 × 4

 0101
 × 5

Table 58. System PLL Multiplication Factors

As described in Section 19, "Clocking," The LBCM, DDRCM, and SPMF parameters in the reset configuration word low and the CFG_CLKIN_DIV configuration input signal select the ratio between the primary clock input (SYS_CLK_IN or PCI_SYNC_IN) and the internal coherent system bus clock (csb_clk). Table 59 shows the expected frequency values for the CSB frequency for select csb_clk to SYS_CLK_IN/PCI_SYNC_IN ratios.

 \times 6

Reserved

0110

0111-1111

Table 59. CSB Frequency Options

| CFG_CLKIN_DIV | SPMF | csb_clk: Input Clock Ratio ² | Input Clock Frequency(MHz) ² | | | |
|-----------------------|--------|---|---|---------|----------------|-------|
| at reset ¹ | SFINIF | | 24 | 25 | 33.33 | 66.67 |
| | | | | csb_clk | Frequency(MHz) | |
| High | 0010 | 2:1 | | | | 133 |
| High | 0011 | 3 : 1 | | | 100 | |
| High | 0100 | 4:1 | | 100 | 133 | |
| High | 0101 | 5:1 | 120 | 125 | 167 | |
| High | 0110 | 6:1 | 144 | 150 | | |
| Low | 0010 | 2:1 | | | | 133 |
| Low | 0011 | 3:1 | | | 100 | |
| Low | 0100 | 4 : 1 | | 100 | 133 | |

| Table 59. | CSB Freque | ency Options | (continued) |
|-----------|------------|--------------|-------------|
| | | | |

| CFG_CLKIN_DIV | csb_clk: | | Input Clock Frequency(MHz) ² | | | | | | |
|-----------------------|----------|-----------------------------------|---|----------|----------------|-------|--|--|--|
| at reset ¹ | OI WII | Input Clock Ratio ² | 24 | 25 33.33 | | 66.67 | | | |
| | | | | csb_clk | Frequency(MHz) | | | | |
| Low | 0101 | 5:1 | 120 | 125 | 167 | | | | |
| Low | 0110 | 6:1 | 144 | 150 | | | | | |

¹ CFG_CLKIN_DIV select the ratio between SYS_CLK_IN and PCI_SYNC_OUT.

19.2 Core PLL Configuration

RCWL[COREPLL] selects the ratio between the internal coherent system bus clock (*csb_clk*) and the e300 core clock (*core_clk*). Table 60 shows the encodings for RCWL[COREPLL]. COREPLL values that are not listed in Table 60 should be considered as reserved.

NOTE

Core VCO frequency = Core frequency \times VCO divider VCO divider has to be set properly so that the core VCO frequency is in the range of 400–800 MHz.

Table 60. e300 Core PLL Configuration

| RC | RCWL[COREPLL] | | core_clk: csb_clk Ratio | VCO divider ¹ | | |
|-----|------------------|---|---|--|--|--|
| 0–1 | 2–5 | 6 | COTE_CIN . CSD_CIN Hatto | VCO dividei | | |
| nn | 0000 | 0 | PLL bypassed (PLL off, <i>csb_clk</i> clocks core directly) | PLL bypassed (PLL off, csb_clk clocks core directly) | | |
| 11 | nnnn | n | n/a | n/a | | |
| 00 | 0001 | 0 | 1:1 | 2 | | |
| 01 | 0001 | 0 | 1:1 | 4 | | |
| 10 | 0001 | 0 | 1:1 | 8 | | |
| 00 | 0001 | 1 | 1.5:1 | 2 | | |
| 01 | 0001 | 1 | 1.5:1 | 4 | | |
| 10 | 0001 | 1 | 1.5:1 | 8 | | |
| 00 | 0010 | 0 | 2:1 | 2 | | |
| 01 | 0010 | 0 | 2:1 | 4 | | |
| 10 | 0010 | 0 | 2:1 | 8 | | |
| 00 | 0010 | 1 | 2.5:1 | 2 | | |
| 01 | 01 0010 1 | | 2.5:1 | 4 | | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

 $^{^2 \;\;}$ SYS_CLK_IN is the input clock in host mode; PCI_CLK is the input clock in agent mode.

Clocking

Table 60. e300 Core PLL Configuration (continued)

| RCWL[COREPLL] | | PLL] | core_clk: csb_clk Ratio | VCO divider ¹ |
|---------------|------|------|-------------------------|--------------------------|
| 0–1 | 2–5 | 6 | COTE_CIR. CSD_CIR Hallo | VOO dividei |
| 10 | 0010 | 1 | 2.5:1 | 8 |
| 00 | 0011 | 0 | 3:1 | 2 |
| 01 | 0011 | 0 | 3:1 | 4 |
| 10 | 0011 | 0 | 3:1 | 8 |

¹ Core VCO frequency = Core frequency × VCO divider. Note that VCO divider has to be set properly so that the core VCO frequency is in the range of 400-800MHz.

19.3 Example Clock Frequency Combinations

Table 61 shows several possible frequency combinations that can be selected based on the indicated input reference frequencies, with RCWLR[LBCM] = 0 and RCWLR[DDRCM] = 1, such that the LBC operates with a frequency equal to the frequency of csb_clk and the DDR controller operates at twice the frequency of csb_clk.

Table 61. System Clock Frequencies

| | | | | | | | LBC(| lbc_cl | k) | e: | 300 Cc | re(co | re_clk) | ١ |
|----------------------------|-----------|-----------|-------|------------------|------------------|------|-------|--------|-------------------------|-------|--------|-------|---------|-----|
| SYS_CLK_ IN/ PCI_CLK | SPMF 1 | vcod 2 | vco | CSB(csb_ clk) | DDR (ddr_clk) | /2 | /4 | /8 | USB ref ³ | ×1 | × 1.5 | ×2 | × 2.5 | ×3 |
| 24.0 | 6 | 2 | 576.0 | 144.0 | 288.0 | | 36 | 18.0 | 12.0 | 144.0 | 216 | 288 | 360 | |
| 24.0 | 5 | 2 | 480.0 | 120.0 | 240.0 | 60 | 30 | 15.0 | 12.0 | 120.0 | 180 | 240 | 300 | 360 |
| | | | | | | | | | | | | | | |
| 25.0 | 6 | 2 | 600.0 | 150.0 | 300.0 | | 37.5 | 18.8 | Note 1 | 150.0 | 225 | 300 | 375 | |
| 25.0 | 5 | 2 | 500.0 | 125.0 | 250.0 | 62.5 | 31.25 | 15.6 | Note1 | 125.0 | 188 | 250 | 313 | 375 |
| | | | | | | | | | | | | | | |
| 32.0 | 5 | 2 | 640.0 | 160.0 | 320.0 | | 40 | 20.0 | 16.0 | 160.0 | 240 | 320 | | |
| 32.0 | 4 | 2 | 512.0 | 128.0 | 256.0 | 64 | 32 | 16.0 | 16.0 | 128.0 | 192 | 256 | 320 | 384 |
| | | | | | | | | | | | | | | |
| 33.3 | 5 | 2 | 666.0 | 166.5 | 333.0 | | 41.63 | 20.8 | Note 1 | 166.5 | 250 | 333 | | |
| 33.3 | 4 | 2 | 532.8 | 133.2 | 266.4 | 66.6 | 33.3 | 16.7 | Note 1 | 133.2 | 200 | 266 | 333 | 400 |
| | | | | | | | | | | | | | | |
| 48.0 | 3 | 2 | 576.0 | 144.0 | 288.0 | | 36 | 18.0 | 48.0 | 144.0 | 216 | 288 | 360 | |

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Clocking

Table 61. System Clock Frequencies (continued)

| 66.7 | 2 | 2 | 533.4 | 133.3 | 266.7 | 66.7 | 33.34 | 16.7 | Note 1 | 133.3 | 200 | 267 | 333 | 400 |
|------|---|---|-------|-------|-------|------|-------|------|--------|-------|-----|-----|-----|-----|

Note:

Note 1: USB reference clock must be supplied from a separate source as it must be 12, 16 or 48 MHz, the USB reference must be supplied from a separate external source using USB_CLK_IN. Note 2: When considering operating frequencies, the valid system APLL VCO operating range of 400-800 MHz must not be violated.

Note 3: csb_clk frequencies of less than 133MHz will not support Gigabit Ethernet data rates.

- System PLL Multiplication Factor
- System PLL VCO Divider
- ³ Frequency of USB PLL Input reference

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Thermal

20 Thermal

This section describes the thermal specifications of the MPC8313E.

20.1 Thermal Characteristics

Table 62 provides the package thermal characteristics for the 516 27×27 mm TEPBGAII.

Table 62. Package Thermal Characteristics for TEPBGAII

| Characteristic | Board type | Symbol | TEPBGAII | Unit | Notes |
|---|-------------------------|------------------|----------|------|-------|
| Junction to Ambient Natural Convection | Single layer board (1s) | $R_{	hetaJA}$ | 25 | °C/W | 1,2 |
| Junction to Ambient Natural Convection | Four layer board (2s2p) | $R_{	heta JA}$ | 18 | °C/W | 1,2,3 |
| Junction to Ambient (@200 ft/min) | Single layer board (1s) | $R_{\theta JMA}$ | 20 | °C/W | 1,3 |
| Junction to Ambient (@200 ft/min) | Four layer board (2s2p) | $R_{\theta JMA}$ | 15 | °C/W | 1,3 |
| Junction to Board | | $R_{\theta JB}$ | 10 | °C/W | 4 |
| Junction to Case | | $R_{\theta JC}$ | 8 | °C/W | 5 |
| Junction to Package Top | Natural Convection | Ψ_{JT} | 7 | °C/W | 6 |

Notes:

- 1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- 2. Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
- 3. Per JEDEC JESD51-6 with the board horizontal.
- 4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
- Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

20.2 Thermal Management Information

For the following sections, $P_D = (V_{DD} \times I_{DD}) + P_{I/O}$ where $P_{I/O}$ is the power dissipation of the I/O drivers.

20.2.1 Estimation of Junction Temperature with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T_J , can be obtained from the equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$
 where:
$$T_J = \text{junction temperature (°C)}$$

$$T_A = \text{ambient temperature for the package (°C)}$$

$$R_{\theta JA} = \text{junction to ambient thermal resistance (°C/W)}$$

$$P_D = \text{power dissipation in the package (W)}$$

The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. As a general statement, the value obtained on a single layer board is appropriate for a tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated. Test cases have demonstrated that errors of a factor of two (in the quantity $T_I - T_A$) are possible.

20.2.2 Estimation of Junction Temperature with Junction-to-Board Thermal Resistance

The thermal performance of a device cannot be adequately predicted from the junction to ambient thermal resistance. The thermal performance of any component is strongly dependent on the power dissipation of surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter (edge) of the package will be approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

At a known board temperature, the junction temperature is estimated using the following equation:

```
T_J = T_B + (R_{\theta JB} \times P_D) where: T_J = \text{junction temperature (°C)} T_B = \text{board temperature at the package perimeter (°C)} R_{\theta JB} = \text{junction to board thermal resistance (°C/W) per JESD51-8} P_D = \text{power dissipation in the package (W)}
```

When the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. The application board should be similar to the thermal test condition: the component is soldered to a board with internal planes.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

20.2.3 Experimental Determination of Junction Temperature

To determine the junction temperature of the device in the application after prototypes are available, the Thermal Characterization Parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$\begin{split} T_J &= T_T + (\Psi_{JT} \times P_D) \\ \text{where:} \\ T_J &= \text{junction temperature (°C)} \\ T_T &= \text{thermocouple temperature on top of package (°C)} \\ \Psi_{JT} &= \text{thermal characterization parameter (°C/W)} \\ P_D &= \text{power dissipation in the package (W)} \end{split}$$

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

20.2.4 Heat Sinks and Junction-to-Case Thermal Resistance

In some application environments, a heat sink will be required to provide the necessary thermal management of the device. When a heat sink is used, the thermal resistance is expressed as the sum of a junction to case thermal resistance and a case to ambient thermal resistance:

```
R_{\theta JA} = R_{\theta JC} + R_{\theta CA} where: R_{\theta JA} = \text{junction to ambient thermal resistance (°C/W)} R_{\theta JC} = \text{junction to case thermal resistance (°C/W)} R_{\theta CA} = \text{case to ambient thermal resistance (°C/W)}
```

 $R_{\theta IC}$ is device related and cannot be influenced by the user. The user controls the thermal environment to change the case to ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

To illustrate the thermal performance of the devices with heat sinks, the thermal performance has been simulated with a few commercially available heat sinks. The heat sink choice is determined by the application environment (temperature, air flow, adjacent component power dissipation) and the physical space available. Because there is not a standard application environment, a standard heat sink is not required.

Table 63. Heat Sinks and Junction-to-Case Thermal Resistance of MPC8313E (TEPBGAII)

| | | 35x35 mm TBGA |
|---|--------------------|---|
| Heat Sink Assuming Thermal Grease | Air Flow | Junction-to-Ambient Thermal Resistance |
| AAVID 30x30x9.4 mm Pin Fin | Natural Convection | 10.7 |
| AAVID 30x30x9.4 mm Pin Fin | 1 m/s | 6.2 |
| AAVID 30x30x9.4 mm Pin Fin | 2 m/s | 5.3 |
| AAVID 31x35x23 mm Pin Fin | Natural Convection | 8.1 |
| AAVID 31x35x23 mm Pin Fin | 1 m/s | 4.4 |
| AAVID 31x35x23 mm Pin Fin | 2 m/s | 3.7 |
| Wakefield, 53x53x25 mm Pin Fin | Natural Convection | 5.4 |
| Wakefield, 53x53x25 mm Pin Fin | 1 m/s | 3.2 |
| Wakefield, 53x53x25 mm Pin Fin | 2 m/s | 2.4 |
| MEI, 75x85x12 no adjacent board, extrusion | Natural Convection | 6.4 |
| MEI, 75x85x12 no adjacent board, extrusion | 1 m/s | 3.8 |
| MEI, 75x85x12 no adjacent board, extrusion | 2 m/s | 2.5 |
| MEI, 75x85x12 mm, adjacent board, 40 mm Side bypass | 1 m/s | 2.8 |

Accurate thermal design requires thermal modeling of the application environment using computational fluid dynamics software which can model both the conduction cooling and the convection cooling of the air moving through the application. Simplified thermal models of the packages can be assembled using the junction-to-case and junction-to-board thermal resistances listed in the thermal resistance table. More detailed thermal models can be made available on request.

Heat sink Vendors include the following list:

Aavid Thermalloy 603-224-9988

80 Commercial St. Concord, NH 03301

Internet: www.aavidthermalloy.com

Alpha Novatech 408-749-7601

473 Sapena Ct. #12 Santa Clara, CA 95054

Internet: www.alphanovatech.com

International Electronic Research Corporation (IERC) 818-842-7277

413 North Moss St. Burbank, CA 91502

Internet: www.ctscorp.com

Thermal

Millennium Electronics (MEI) 408-436-8770

Loroco Sites

671 East Brokaw Road San Jose, CA 95112

Internet: www.mei-thermal.com

Tyco Electronics 800-522-6752

Chip CoolersTM P.O. Box 3668

Harrisburg, PA 17105

Internet: www.chipcoolers.com

Wakefield Engineering 603-635-2800

33 Bridge St. Pelham, NH 03076

Internet: www.wakefield.com

Interface material vendors include the following:

Chomerics, Inc. 781-935-4850

77 Dragon Ct. Woburn, MA 01801

Internet: www.chomerics.com

Dow-Corning Corporation 800-248-2481

Corporate Center PO BOX 994

Midland, MI 48686-0994

Internet: www.dowcorning.com

Shin-Etsu MicroSi, Inc. 888-642-7674

10028 S. 51st St. Phoenix, AZ 85044

Internet: www.microsi.com

The Bergquist Company 800-347-4572

18930 West 78th St. Chanhassen, MN 55317

Internet: www.bergquistcompany.com

20.3 Heat Sink Attachment

When attaching heat sinks to these devices, an interface material is required. The best method is to use thermal grease and a spring clip. The spring clip should connect to the printed circuit board, either to the board itself, to hooks soldered to the board, or to a plastic stiffener. Avoid attachment forces which would lift the edge of the package or peel the package from the board. Such peeling forces reduce the solder joint lifetime of the package. Recommended maximum force on the top of the package is 10 lb (4.5 kg) force. If an adhesive attachment is planned, the adhesive should be intended for attachment to painted or plastic surfaces and its performance verified under the application requirements.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications. Rev. 0

20.3.1 Experimental Determination of the Junction Temperature with a Heat Sink

When heat sink is used, the junction temperature is determined from a thermocouple inserted at the interface between the case of the package and the interface material. A clearance slot or hole is normally required in the heat sink. Minimizing the size of the clearance is important to minimize the change in thermal performance caused by removing part of the thermal interface to the heat sink. Because of the experimental difficulties with this technique, many engineers measure the heat sink temperature and then back calculate the case temperature using a separate measurement of the thermal resistance of the interface. From this case temperature, the junction temperature is determined from the junction to case thermal resistance.

$$T_J = T_C + (R_{\theta JC} x P_D)$$

Where:

 T_J = junction temperature (°C)

 T_C = case temperature of the package

 $R_{\theta IC}$ = junction-to-case thermal resistance

 P_D = power dissipation

21 System Design Information

This section provides electrical and thermal design recommendations for successful application of the MPC8313E SYS_CLK_IN

21.1 System Clocking

The MPC8313E includes two PLLs.

- The platform PLL (AV_{DD2}) generates the platform clock from the externally supplied SYS_CLK_IN input in PCI host mode or SYS_CLK_IN/PCI_SYNC_IN in PCI agent mode. The frequency ratio between the platform and SYS_CLK_IN is selected using the platform PLL ratio configuration bits as described in Section 19.1, "System PLL Configuration."
- 2. The e300 Core PLL (AV_{DD1}) generates the core clock as a slave to the platform clock. The frequency ratio between the e300 core clock and the platform clock is selected using the e300 PLL ratio configuration bits as described in Section 19.2, "Core PLL Configuration."

21.2 PLL Power Supply Filtering

Each of the PLLs listed above is provided with power through independent power supply pins (AV_{DD1} , AV_{DD2} respectively). The AV_{DD} level should always be equivalent to V_{DD} , and preferably these voltages will be derived directly from V_{DD} through a low frequency filter scheme such as the following.

There are a number of ways to reliably provide power to the PLLs, but the recommended solution is to provide five independent filter circuits as illustrated in Figure 40, one to each of the five AV_{DD} pins. By providing independent filters to each PLL the opportunity to cause noise injection from one PLL to the other is reduced.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

System Design Information

This circuit is intended to filter noise in the PLLs resonant frequency range from a 500 kHz to 10 MHz range. It should be built with surface mount capacitors with minimum Effective Series Inductance (ESL). Consistent with the recommendations of Dr. Howard Johnson in *High Speed Digital Design: A Handbook of Black Magic* (Prentice Hall, 1993), multiple small capacitors of equal value are recommended over a single large value capacitor.

Each circuit should be placed as close as possible to the specific AV_{DD} pin being supplied to minimize noise coupled from nearby circuits. It should be possible to route directly from the capacitors to the AV_{DD} pin, which is on the periphery of package, without the inductance of vias.

Figure 40 shows the PLL power supply filter circuit.

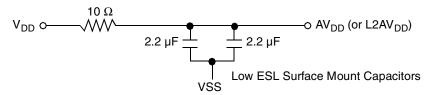


Figure 40. PLL Power Supply Filter Circuit

21.3 Decoupling Recommendations

Due to large address and data buses, and high operating frequencies, the device can generate transient power surges and high frequency noise in its power supply, especially while driving large capacitive loads. This noise must be prevented from reaching other components in the MPC8313E system, and the MPC8313E itself requires a clean, tightly regulated source of power. Therefore, it is recommended that the system designer place at least one decoupling capacitor at each V_{DD} , NV_{DD} , GV_{DD} , LV_{DD} , LV_{DDA} , and LV_{DDB} pins of the device. These decoupling capacitors should receive their power from separate V_{DD} , NV_{DD} , $NV_{$

These capacitors should have a value of 0.01 or $0.1~\mu F$. Only ceramic SMT (surface mount technology) capacitors should be used to minimize lead inductance, preferably 0402 or 0603 sizes.

In addition, it is recommended that there be several bulk storage capacitors distributed around the PCB, feeding the V_{DD} , NV_{DD} , GV_{DD} , LV_{DD} , LV_{DDA} , and LV_{DDB} planes, to enable quick recharging of the smaller chip capacitors. These bulk capacitors should have a low ESR (equivalent series resistance) rating to ensure the quick response time necessary. They should also be connected to the power and ground planes through two vias to minimize inductance. Suggested bulk capacitors—100–330 μ F (AVX TPS tantalum or Sanyo OSCON).

21.4 Connection Recommendations

To ensure reliable operation, it is highly recommended to connect unused inputs to an appropriate signal level. Unused active low inputs should be tied to NV_{DD} , GV_{DD} , LV_{DD} , LV_{DDA} or LV_{DDB} as required. Unused active high inputs should be connected to VSS. All NC (no-connect) signals must remain unconnected.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

Power and ground connections must be made to all external V_{DD}, NV_{DD}, GV_{DD}, LV_{DD}, LV_{DDA}, LV_{DDB}, and VSS pins of the device.

21.5 Output Buffer DC Impedance

The MPC8313E drivers are characterized over process, voltage, and temperature. For all buses, the driver is a push-pull single-ended driver type (open drain for I²C).

To measure Z_0 for the single-ended drivers, an external resistor is connected from the chip pad to NV_{DD} or VSS. Then, the value of each resistor is varied until the pad voltage is $NV_{DD}/2$ (see Figure 41). The output impedance is the average of two components, the resistances of the pull-up and pull-down devices. When data is held high, SW1 is closed (SW2 is open) and R_P is trimmed until the voltage at the pad equals $NV_{DD}/2$. R_P then becomes the resistance of the pull-up devices. R_P and R_N are designed to be close to each other in value. Then, $Z_0 = (R_P + R_N)/2$.

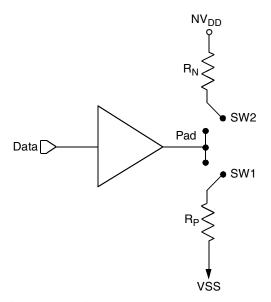


Figure 41. Driver Impedance Measurement

The value of this resistance and the strength of the driver's current source can be found by making two measurements. First, the output voltage is measured while driving logic 1 without an external differential termination resistor. The measured voltage is $V_1 = R_{source} \times I_{source}$. Second, the output voltage is measured while driving logic 1 with an external precision differential termination resistor of value R_{term} . The measured voltage is $V_2 = (1/(1/R_1 + 1/R_2)) \times I_{source}$. Solving for the output impedance gives $R_{source} = R_{term} \times (V_1/V_2 - 1)$. The drive current is then $I_{source} = V_1/R_{source}$.

System Design Information

Table 64 summarizes the signal impedance targets. The driver impedance are targeted at minimum V_{DD} , nominal NV_{DD} , $105^{\circ}C$.

Local Bus, Ethernet, **PCI Signals PCI Output Clocks DUART, Control, Impedance** (not including PCI (including **DDR DRAM Symbol** Unit Configuration, Power output clocks) PCI_SYNC_OUT) Management R_N 42 Target 25 Target 42 Target 20 Target Z_0 Ω R_{P} 42 Target 25 Target 42 Target 20 Target Z_0 Ω Differential NA NA NA NA Z_{DIFF} O

Table 64. Impedance Characteristics

Note: Nominal supply voltages. See Table 1, T_i = 105°C.

21.6 Configuration Pin Muxing

The MPC8313E provides the user with power-on configuration options which can be set through the use of external pull-up or pull-down resistors of 4.7 k Ω on certain output pins (see customer visible configuration pins). These pins are generally used as output only pins in normal operation.

While HRESET is asserted however, these pins are treated as inputs. The value presented on these pins while HRESET is asserted, is latched when PORESET deasserts, at which time the input receiver is disabled and the I/O circuit takes on its normal function. Careful board layout with stubless connections to these pull-up/pull-down resistors coupled with the large value of the pull-up/pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.

21.7 Pull-Up Resistor Requirements

The MPC8313E requires high resistance pull-up resistors ($10 \,\mathrm{k}\Omega$ is recommended) on open drain type pins including I²C pins, Ethernet Management MDIO pin and EPIC interrupt pins.

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 42. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions as most have asynchronous behavior and spurious assertion will give unpredictable results.

Refer to the PCI 2.2 specification for all pull-ups required for PCI.

21.8 JTAG Configuration Signals

Boundary scan testing is enabled through the JTAG interface signals. The TRST signal is optional in IEEE Std. 1149.1, but is provided on all processors that implement the PowerPC architecture. The device requires TRST to be asserted during reset conditions to ensure the JTAG boundary logic does not interfere with normal chip operation. While it is possible to force the TAP controller to the reset state using only the TCK and TMS signals, generally systems will assert TRST during power-on reset. Because the JTAG interface is also used for accessing the common on-chip processor (COP) function, simply tying TRST to PORESET is not practical.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

The COP function of these processors allows a remote computer system (typically, a PC with dedicated hardware and debugging software) to access and control the internal operations of the processor. The COP interface connects primarily through the JTAG port of the processor, with some additional status monitoring signals. The COP port requires the ability to independently assert TRST without causing PORESET. If the target system has independent reset sources, such as voltage monitors, watchdog timers, power supply failures, or push-button switches, then the COP reset signals must be merged into these signals with logic.

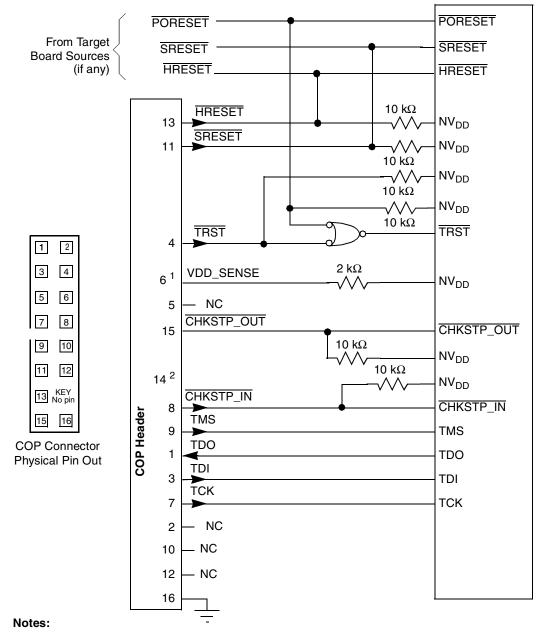
The arrangement shown in Figure 42 allows the COP to independently assert HRESET or TRST, while ensuring that the target can drive HRESET as well. If the JTAG interface and COP header will not be used, TRST should be tied to PORESET so that it is asserted when the system reset signal (PORESET) is asserted.

The COP header shown in Figure 42 adds many benefits—breakpoints, watchpoints, register and memory examination/modification, and other standard debugger features are possible through this interface—and can be as inexpensive as an unpopulated footprint for a header to be added when needed.

The COP interface has a standard header for connection to the target system, based on the 0.025" square-post, 0.100" centered header assembly (often called a Berg header).

There is no standardized way to number the COP header shown in Figure 42; consequently, many different pin numbers have been observed from emulator vendors. Some are numbered top-to-bottom then left-to-right, while others use left-to-right then top-to-bottom, while still others number the pins counter clockwise from pin 1 (as with an IC). Regardless of the numbering, the signal placement recommended in Figure 42 is common to all known emulators.

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications. Rev. 0



- 1. Some systems require power to be fed from the application board into the debugger repeater card via the COP header. In this case the resistor value for VDD_SENSE should be around 20Ω .
- 2. Key location; pin 14 is not physically present on the COP header.

Figure 42. JTAG Interface Connection

MPC8313E PowerQUICC[™] II Pro Processor Hardware Specifications, Rev. 0

22 Document Revision History

Table 22-61 provides a revision history for this hardware specification.

Table 65. Document Revision History

| Revision | Date | Substantive Change(s) |
|----------|---------|-----------------------|
| 0 | 06/2007 | Initial release. |

23 Ordering Information

Ordering information for the parts fully covered by this specification document is provided in Section 23.1, "Part Numbers Fully Addressed by This Document."

23.1 Part Numbers Fully Addressed by This Document

Table 66 provides the Freescale part numbering nomenclature for the MPC8313E. Note that the individual part numbers correspond to a maximum processor core frequency. For available frequencies, contact your local Freescale sales office. In addition to the processor frequency, the part numbering scheme also includes an application modifier which may specify special application conditions. Each part number also contains a revision code which refers to the die mask revision number.

Table 66. Part Numbering Nomenclature

| IVIPC | ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,, | e | Ι | pρ | аа | а | X |
|-----------------|---|---|---------------------------------------|-------------------------|-------------------------------------|------------------|---|
| Product Code | Part Identifier | Encryption Acceleration | Temperature Range ³ | Package ¹ | e300 core Frequency ² | DDR Frequency | Revision Level |
| MPC | 8313 | Blank = Not included E = included | Blank = 0 to 105°C C= -40 to 105°C | VR= PB free TEPBGAII | AF = 333MHz | F = 333 MHz | Contact local Freescale sales office |

Notes:

MDC

- 1. See Section 18, "Package and Pin Listings," for more information on available package types.
- 2. Processor core frequencies supported by parts addressed by this specification only. Not all parts described in this specification support all core frequencies. Additionally, parts addressed by Part Number Specifications may support other maximum core frequencies.
- 3. Contact local Freescale office on availability of parts with C temperature range

How to Reach Us:

Home Page:

www.freescale.com

email:

support@freescale.com

USA/Europe or Locations Not Listed:

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 1-800-521-6274 480-768-2130 support@freescale.com

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH
Technical Information Center
Schatzbogen 7
81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
+49 89 92103 559 (German)
+33 1 69 35 48 48 (French)
support@freescale.com

Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku Tokyo 153-0064, Japan 0120 191014 +81 3 5437 9125 support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd.
Technical Information Center
2 Dai King Street
Tai Po Industrial Estate,
Tai Po, N.T., Hong Kong
+800 2666 8080
support.asia@freescale.com

For Literature Requests Only:

Freescale Semiconductor
Literature Distribution Center
P.O. Box 5405
Denver, Colorado 80217
1-800-441-2447
303-675-2140
Fax: 303-675-2150
LDCForFreescaleSemiconductor
@ hibbertgroup.com

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale™ and the Freescale logo are trademarks of Freescale Semiconductor, Inc. The Power Architecture and Power.org word marks and the Power and Power.org logos and related marks are trademarks and service marks licensed by Power.org. The described product contains a PowerPC processor core. The PowerPC name is a trademark of IBM Corp. and used under license. IEEE Stds. 802.1™, 802.11™, 802.2™, 802.3™, 1149.1™, and 1588™ are trademarks of the Institute of Electrical and Electronics Engineers, Inc., (IEEE). This product is not endosed or approved by the IEEE. All other product or service names are the property of their respective owners.

© Freescale Semiconductor, Inc., 2007.

Document Number: MPC8313EEC

Rev. 0 06/2007



